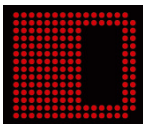


INCT SEMICONDUCTOR NANODEVICES



www.disse.org.br



Members

PUC-Rio

Patrícia Lustoza de Souza

Bruno Horta

Ivan Guillermo Solórzano

UFRJ

Maurício Pamplona Pires

UFMG

Davies William de L. Monteiro

Frank Sill

Franklin Massami Matinaga

Luciana Pedrosa Salles

Omar Paranaíba Villela Neto

Paulo Sérgio Soares Guimarães

Wagner Nunes Rodrigues

USP

Alain André Quivy

Euzi Conceição Fernandes da Silva

CTEx

Adenir da Silva Filho

Leonardo Bruno de Sá

Marcelo Silva Bortolini de Castro

IEAv

Ademar Muraro Jr

Angelo Passaro

Gustavo Soares Vieira

Nancy Mieko Abe

Ruy Morgado de Castro

UFSCar

Nelson Studart

Paulo Eduardo Farinas

UFAM

Eduardo Adriano Cotta

UNIFAP

Henrique Fonseca Filho

Robert Ronald Maguinã Zamora

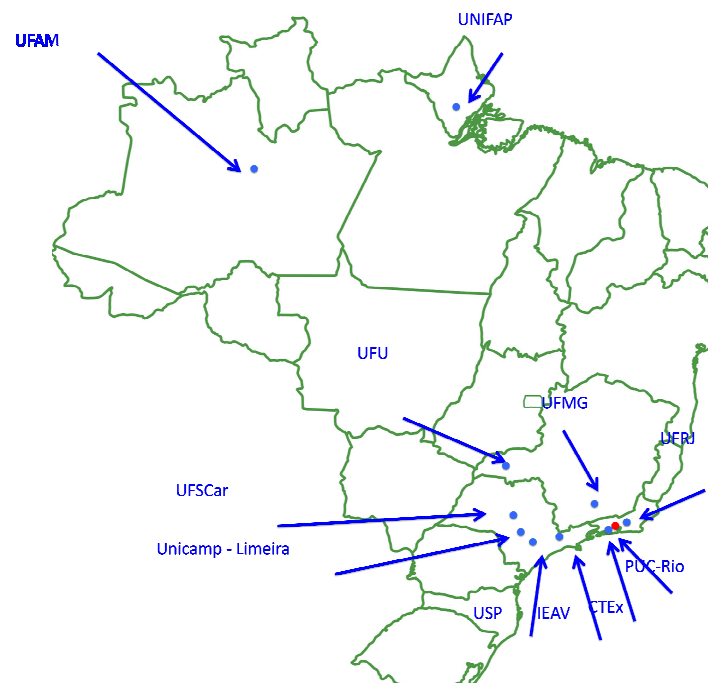
UNICAMP - LIMEIRA

Marcos Henrique Degani

Marcelo Zoéga Maialle

UFU

José Maria Villas Boas





Management Board

The members of the management board are:

Patrícia Lustoza de Souza	PUC-Rio
Paulo Sérgio Soares Guimarães	UFMG
Gustavo Soares Vieira	IEAv
Maurício Pamplona Pires	UFRJ
Nelson Studart	UFSCar



The members responsible for the different missions are:

Paulo Sérgio Soares Guimarães	UFMG	<i>Basic research</i>
Patrícia Lustoza de Souza	PUC-Rio	<i>Technological research</i>
Wagner Nunes Rodrigues	UFMG	<i>Education/training</i>
Nelson Studart	UFSCar	<i>Transfer of knowledge to society/outreach</i>
Gustavo Soares Vieira	IEAv	<i>Transfer of knowledge to industry and government</i>



Research net procedures

Home-page
(www.disse.org.br)

Intranet

Skype

Facebook

Twitter

YouTube

Newsletter

Scientific visits

Periodic small groups meetings

Annual workshops



Prezados membros do DISSE,

As notícias desta semana:

Foi realizado dos dias 13 a 17 o XXVII Encontro Nacional de Física da Matéria Condensada (ENFMC), em Águas de Lindóia, no estado de São Paulo:

<http://www.sbfisica.org.br/~enfmc/2007/>

a) Patrícia Lustosa de Souza (PUC-Rio) participou do Simpósio Temático "Semiconductor Based Devices" com a apresentação "Infrared photodetection and the progress achieved in the field within the INCQ-DISSE", tendo José Maria Villas-Boas (UFU) como "chair" da sessão;

b) Villas-Boas, na palestra convidada, expôs a apresentação "Controlling electron spin in quantum dot molecules". O grupo de Villas-Boas ainda foi responsável pela palestra "Laser induced energy transfer between quantum dots" (com Adamo F. G. do Monte) e pelos pôsteres "Coherent manipulation of excitation-polarization states in a photonic crystal cavity" (com Antônio de Freitas Nieto) e "Probing quantum dot cavity coupling using a nearby empty cavity" (com William J. Lima);

c) Henrique Fonseca Filho (UNIFAP) também participou do ENFMC. Seu grupo foi responsável pelos pôsteres "Surface characterization of Cupuçu (*Theobroma grandiflorum*) leaves" (com Josivan da Silva Costa, Robert Ronald Maguiná Zamora, Marta Duarte da Fonseca de Albuquerque e Elisa Maria Baggio-Satovitch) e "The effect of removal of dental enamel in brackets: a study of atomic force microscopy" (com Karina Figueira da Silva, Robert Ronald Maguiná Zamora, Sandro Figueiredo e Rodrigo Pnoli).

Foram incluídas duas notícias no site do DISSE sobre o "16th Brazilian Workshop on Semiconductor Physics" (BWSP), em Itirapina, São Paulo, realizado na semana passada:

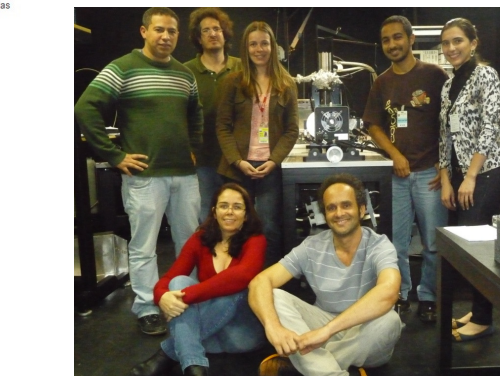
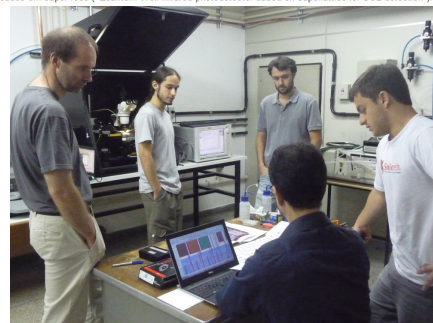
a) O doutorando Renato Teixeira Mourao (UFRJ) apresentou um pôster referente a seu trabalho de mestrado. Nesse trabalho ("Quantum dot optimization for intermediate band solar cells") foram produzidas estruturas de pontos quânticos de InAs sobre AlGaAs para a produção de uma nova classe de células solares de alta eficiência;

<http://www.disse.org.br/ReadNews.aspx?id=100>

b) O aluno de doutorado Germano Maioli Penello apresentou o trabalho sobre fotodetectores baseados em super-rede ("Quantum Well Infrared photodetector based on superlattice for CO2 detection");

<http://www.disse.org.br/ReadNews.aspx?id=103>

DISSE

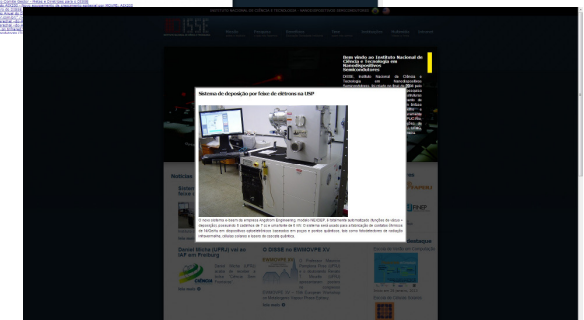
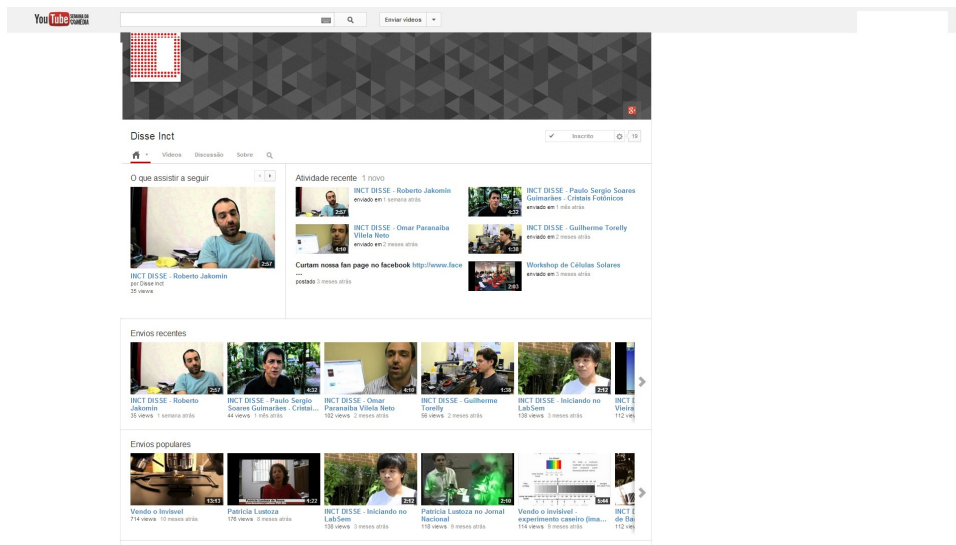
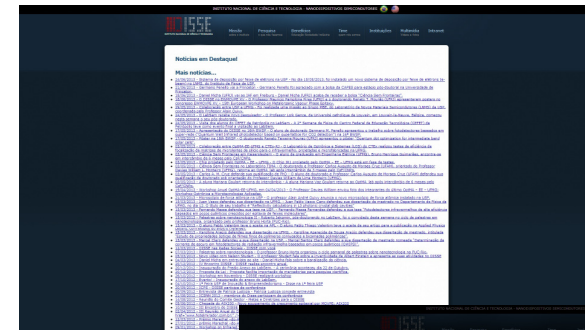
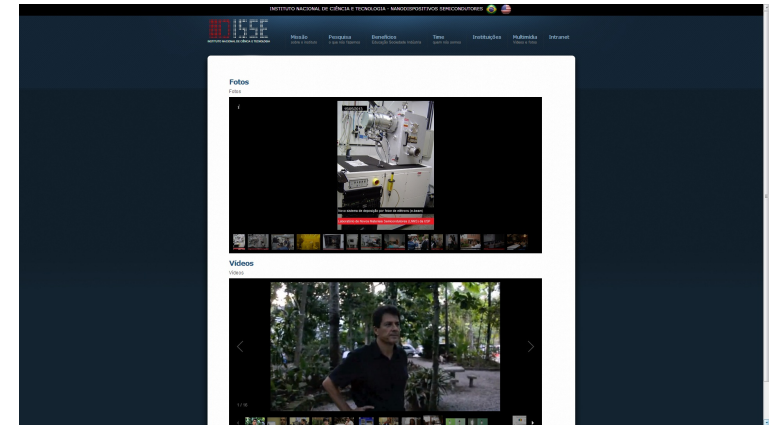


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NANODISPOSITIVOS SEMICONDUTORES





Research net procedures





Research net procedures

Milestones planning

Aims were annually reviewed based on the reports presented at the annual meetings

Use of financial resources:

General lines decided in an extended meeting of the group

Priority for:

- **far-reaching equipment avoiding duplicity when possible**
- **infrastructure for emerging groups with little resources**
- **expensive equipment which cannot be acquired with resources from regular projects**
- **replacement or services on broken equipment which requires fast availability**



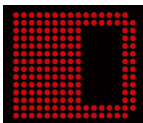
Research net procedures

Search for other financial sources was constantly stimulated.

The group doubled the resources available through local projects financed by FINEP, CNPq, Faperj, Fapemig, Fapesp and CAPES

Mechanisms for implementing the resources transfer to the members

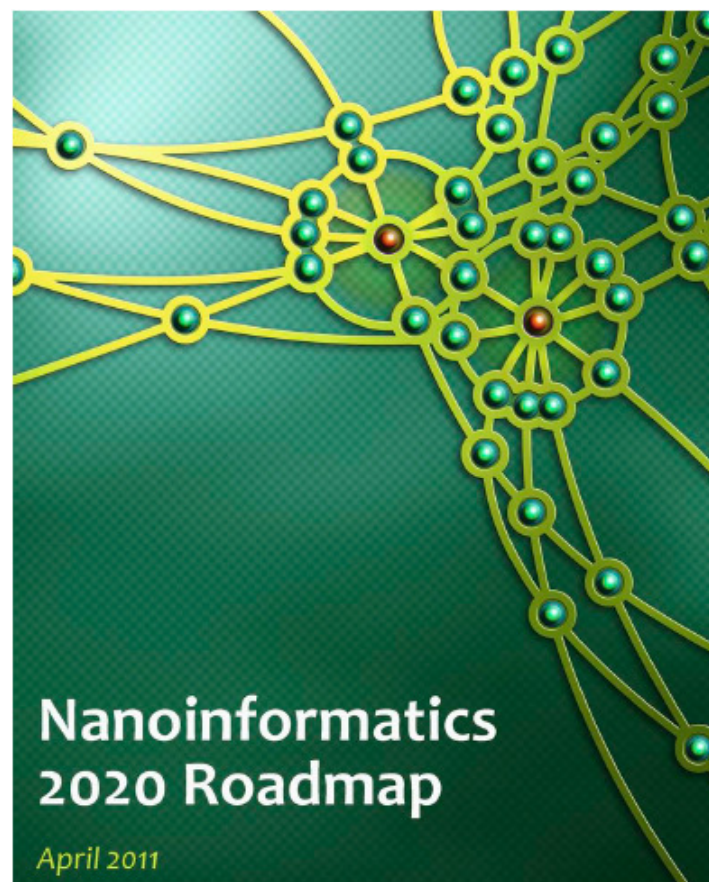
- Each group leader within the INCT had a grant for daily expenses that did not need to be analysed by the management board
- **Simple and fast for national expenses: demands are directly sent to the management board which replies promptly with final decision**
- Very difficult and time consuming to import goods for the member institutions



Nanoinformatics

Nanoinformatics is the science and practice of determining which information is relevant to the nanoscale science, developing and implementing effective mechanisms for collecting, validating, storing, sharing, analyzing and applying the information.

Applied Computational Methods:
Computational Intelligence, Optimization, Data Mining & Machine Learning.



<http://www.internano.org/nanoinformatics/>

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Nanoinformatics

LIMS

“A *Laboratory Information Management System* (LIMS) is a **computational system** applied in the laboratory for **administration** of **samples, standards, experiments, users, tools, materials, protocols** and **automate procedures**”.



Nanoinformatics

NanoTrack: an intelligent LIMS developed for DISSE



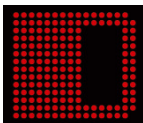
Vilela Neto et al CSBC 2012

Developed by:



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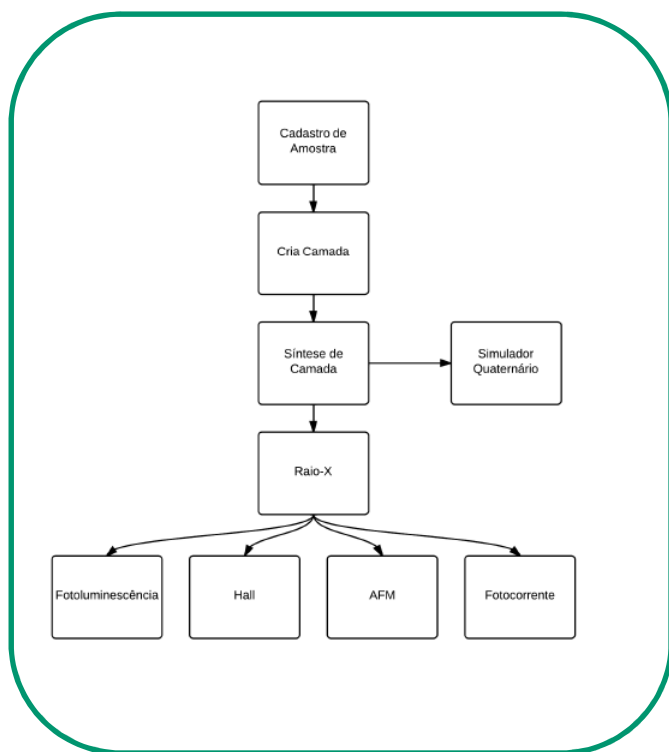




Nanoinformatics

LABSEM Workflow

DISSE information in the
NanoTrack system.



Flux - Workflow - Mozilla Firefox
Flux - Workflow
localhost:8080/NanoTrack/workflowTree.do?action=showActivity&idActivity=10085
Principal Nova Atividade Consulta Tarefas Sair
Versão 1.32.2
Gerenciamento do Workflow
Usuário: suporte

Arvore [Linear]

- Inicio
- Cadastro de Amostra (2012-12-11)
- Cria Camada (2012-12-11)
- Cria Camada (2012-12-11)
- Cria Camada (2012-12-11)
- Síntese Camada (2012-12-11)
- Novo Raio-X
- Novo Simulador Quaternário
- Raio-X (2012-12-11)
- Simulador Quaternário (2012-12-11)
- Cria Camada (2012-12-11)
- Cria Camada (2012-12-11)

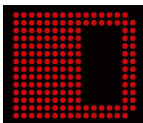
Síntese Camada

Descrição da atividade

Status da atividade: **Aprovado**

RunHyd HP: 2.500 sccm
RunMO HP: 2.600 sccm
RunHyd N: 0 sccm
RunMO N: 0 sccm
SumHyd: 3.000 sccm
SumMO: 3.000 sccm
Q Total: 1
Liner Purge: 1.600 sccm
Total V: 0.001 mol/min
Total III: 0 mol/min
VIII: 24,9
RF Power: 0 kW
Pressão do Reator: 50 mbar
Posição da Válvula: 0°
numAl(Ga+Al): 0
Cat/Ca: 1





Nanoinformatics

DISSE information in the NanoTrack system.

The screenshot displays the NanoTrack web application interface. The browser window title is "Flux - Workflow - Mozilla Firefox". The address bar shows the URL: `localhost:8080/NanoTrack/WorkflowTree.do?action=showActivity&idActivity=10085`. The page title is "Gerenciamento do Workflow" and the version is "Versão 1.32.2". The user is logged in as "Usuário: suporte".

The interface is divided into two main sections:

- Árvore | Linear:** A tree view showing the workflow structure. The selected activity is "Síntese Camada (2012-12-11)", which includes sub-activities like "Novo Raio-X", "Novo Simulador Quaternário", "Raio-X (2012-12-11)", and "Simulador Quaternário (2012-12-11)".
- Síntese Camada:** A detailed view of the selected activity. It shows the "Descrição da atividade" and the "Status da atividade: Aprovado". The following parameters are listed:
 - RunHyd H: 2.500 sccm
 - RunMO H: 2.600 sccm
 - RunHyd N: 0 ascm
 - RunMO N: 0 sccm
 - SumHyd: 3.000 sccm
 - SumMO: 3.000 sccm
 - Q Total: 1
 - Liner Purge: 1.600 sccm
 - Total V: 0,001 m3/min
 - Total III: 0 m3/min
 - VIII: 24,9
 - RF Power: 0 wv
 - Pressão do Reator: 50 mbar
 - Posição da Válvula: 0 -
 - numAll(Ga+Al): 0
 - CallCallAll: 1





Aims

Consolidation of the epitaxial growth center within the institute

Mastering the working mechanisms and the technology of fabrication of mid-infrared semiconductor photodetectors

Development of solar cells based on nanostructures

The group insertion in the international scenario with the development of novel semiconductor nanodevices

Undergraduate and graduate education in the field with both scientific and industrial profile

Technical training

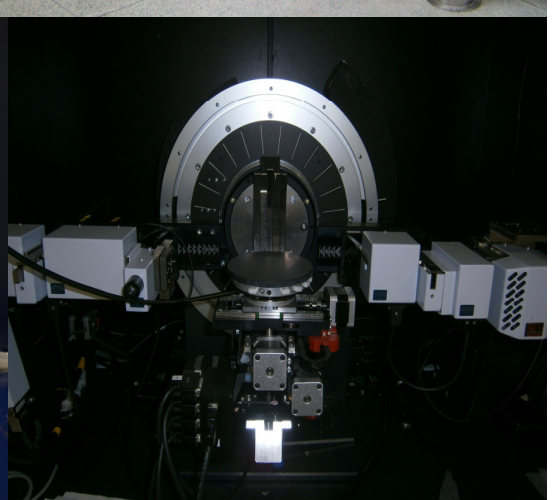
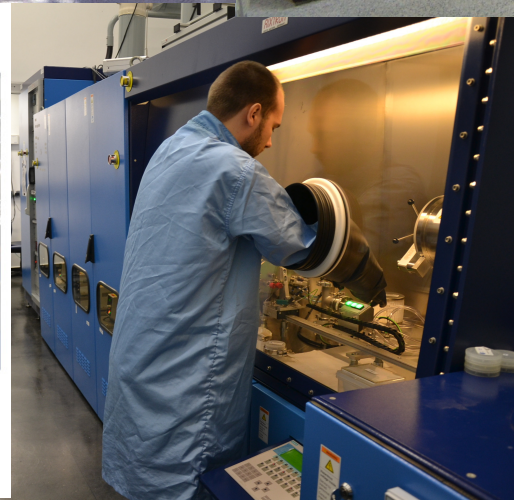
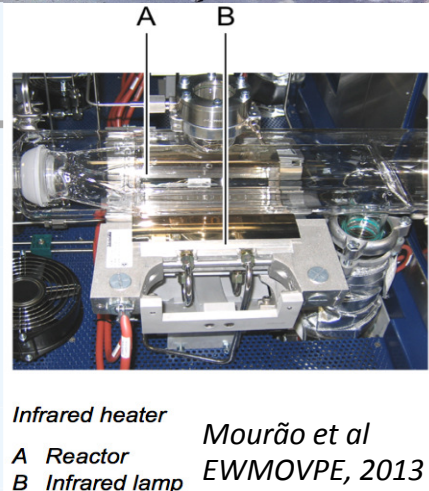
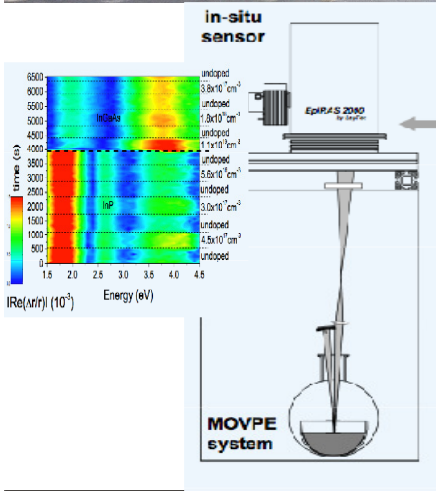
Create conditions for the development of spin-offs

Supplying photodetectors for industry and government offices

Out-reaching actions on the field of research of the institute



Consolidation of the epitaxial growth center



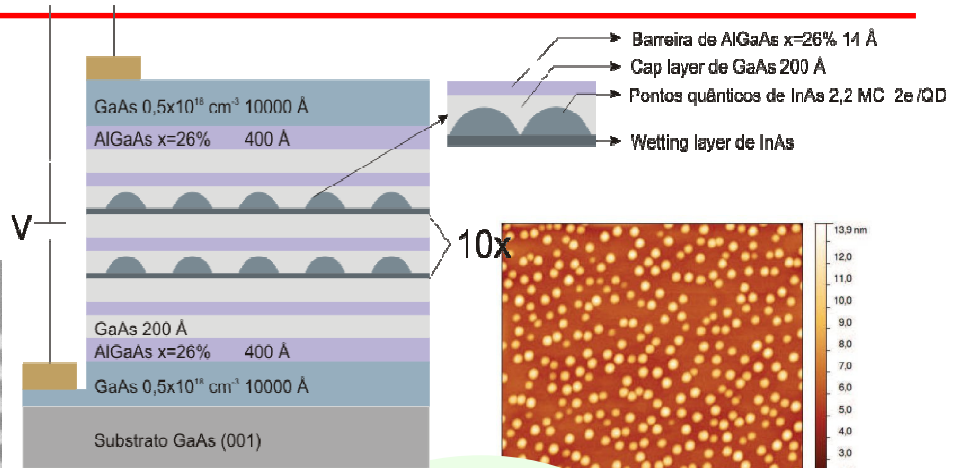
INSTITUTO NACIONAL DE CIÊNCIA E TECNOLOGIA
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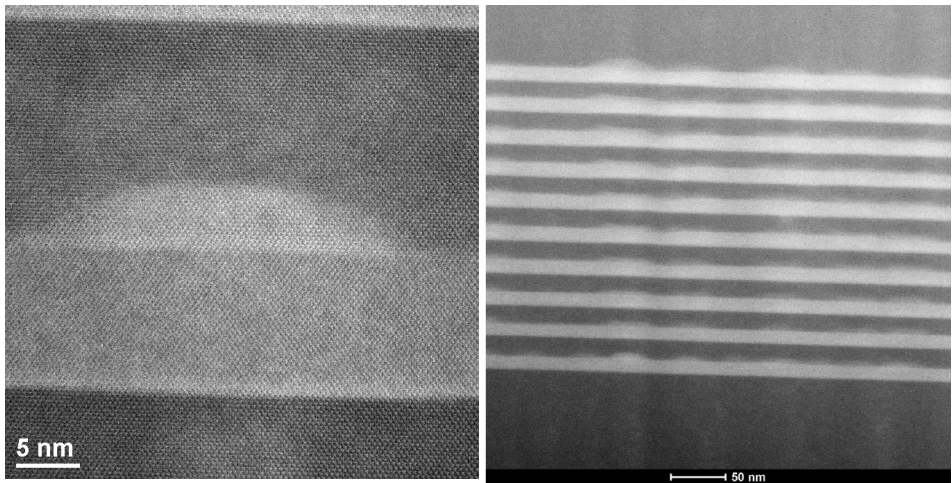
Epitaxial growth of nanostructures

Structures containing quantum dots for QDIPs and tunneling experiments



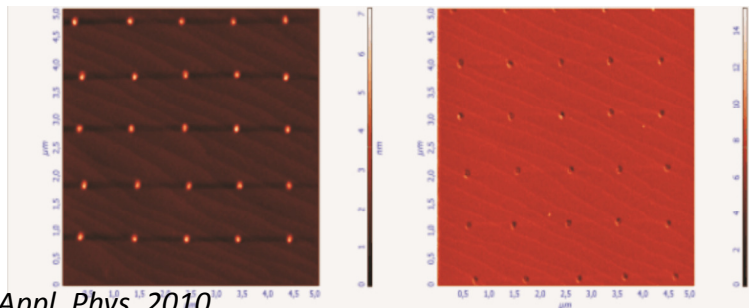
Keizer et al Appl. Phys. Lett. 2012

InAs/GaAs

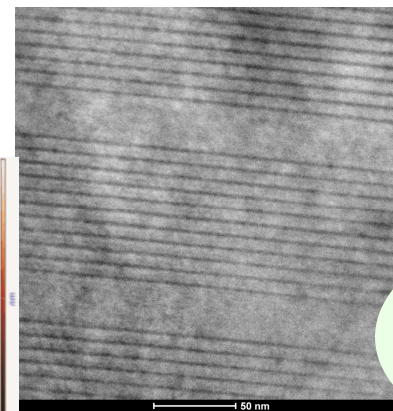


Sandra Landi, collaboration with INMETRO

Site control quantum dot nucleation by AFM



Fonseca Filho et al J. Appl. Phys. 2010



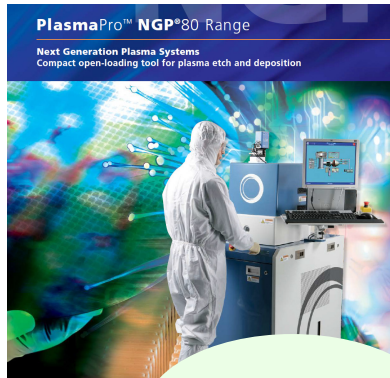
GaAs/AlGaAs superlattices for QWIPs

Penello et al, IEEE J. Quantum Electronics in print



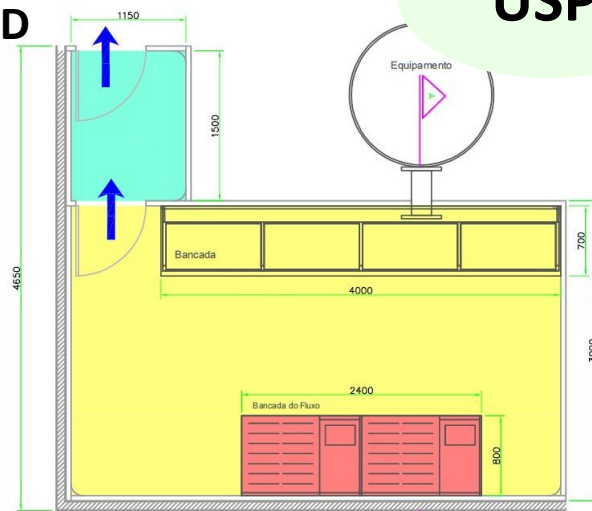


Device fabrication

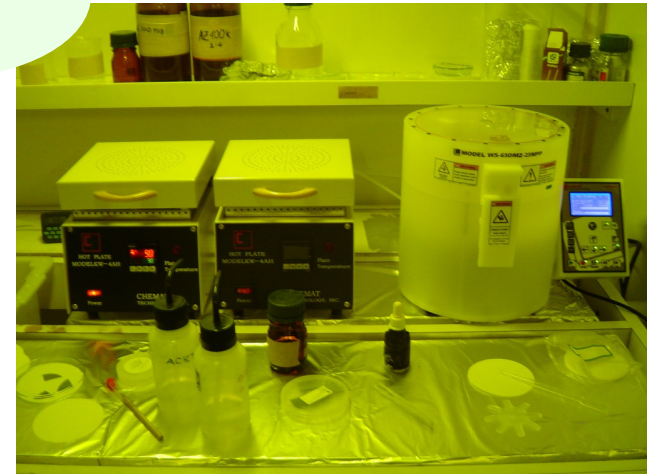


UFMG

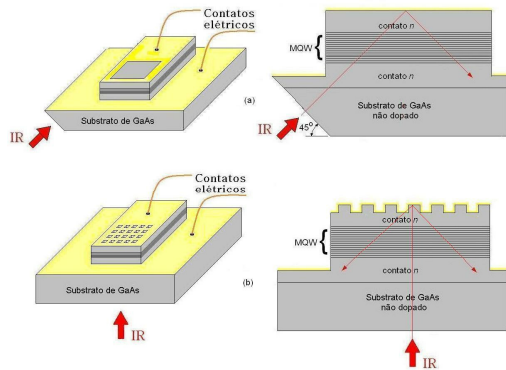
RIE and CVD



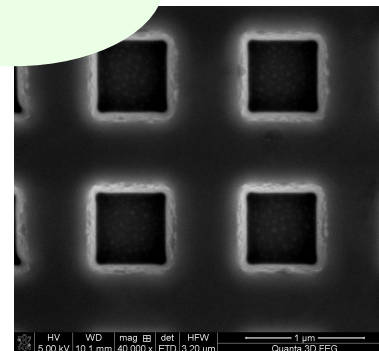
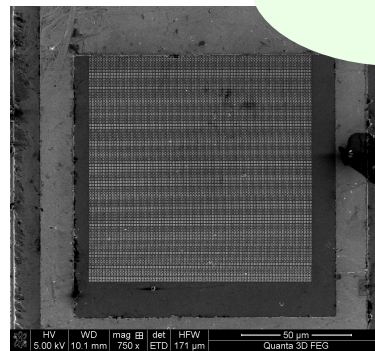
USP



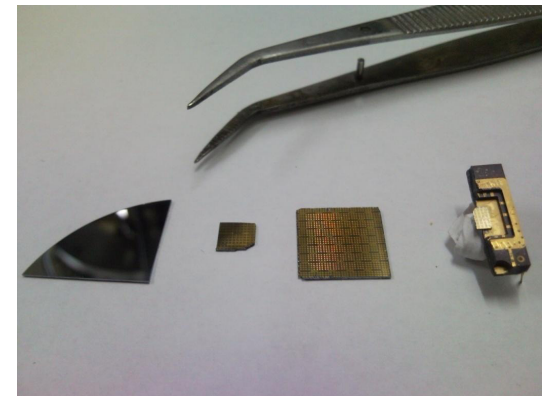
Gratings



UFMG



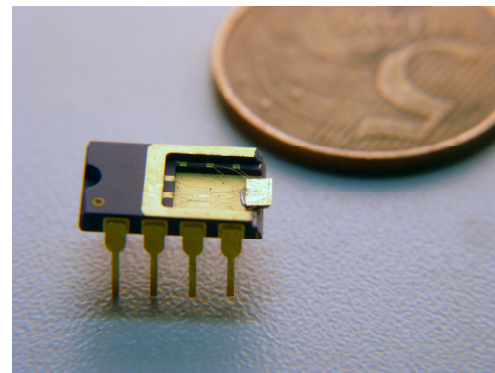
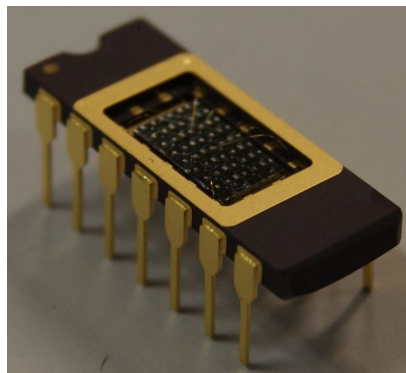
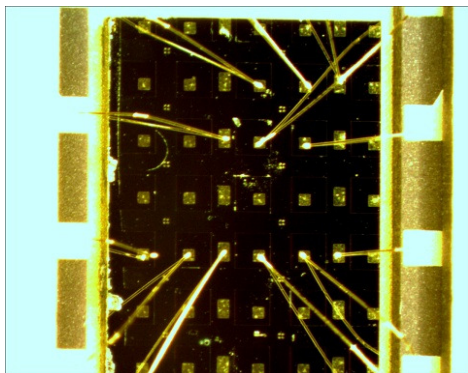
Processing steps



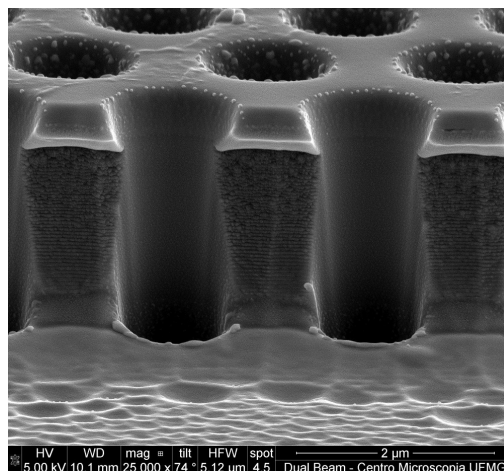
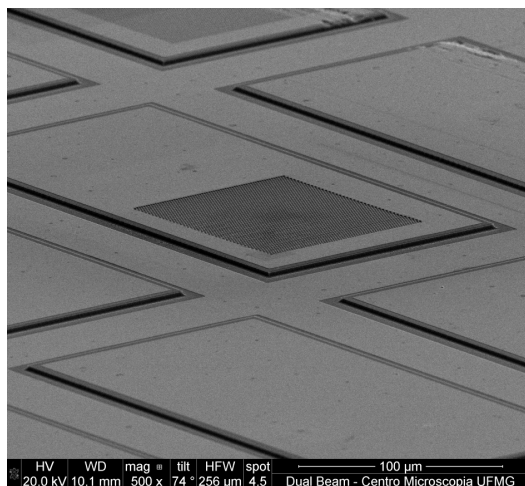


Device fabrication

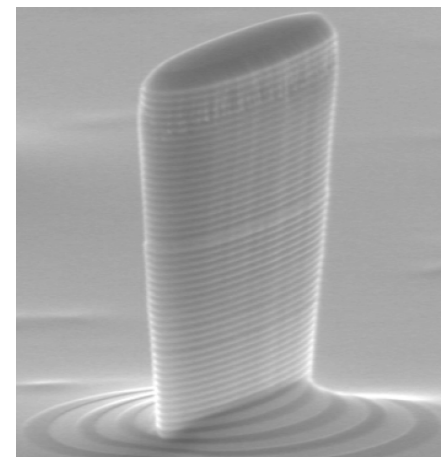
Final devices



Photonic crystals



Pillars

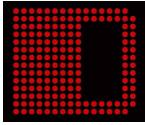




Mastering the working mechanisms and the technology of fabrication of mid-infrared semiconductor photodetectors

Four parallel tracks were followed:

- Production of different photodetectors
- Understanding of the physical mechanisms involved in current generation and collection
- Development of the required circuitry for the read-outs of the photodetectors
- Design and fabrication of equipment which uses photodetection for relevant applications

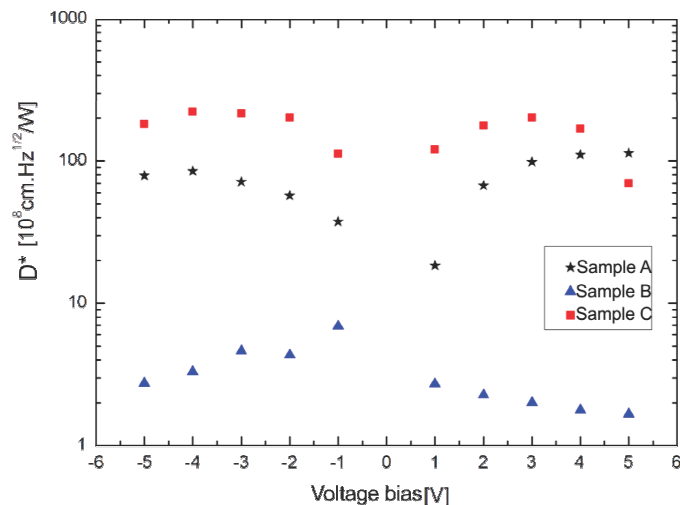


Mastering the working mechanisms and the technology of fabrication of mid-infrared semiconductor photodetectors

Production of photodetectors for operation at different wavelengths

Quantum well infrared photodetectors - QWIPs

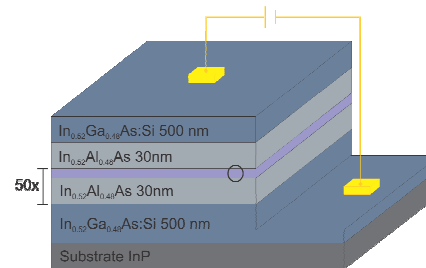
InGaAs/InAlAs QWIP



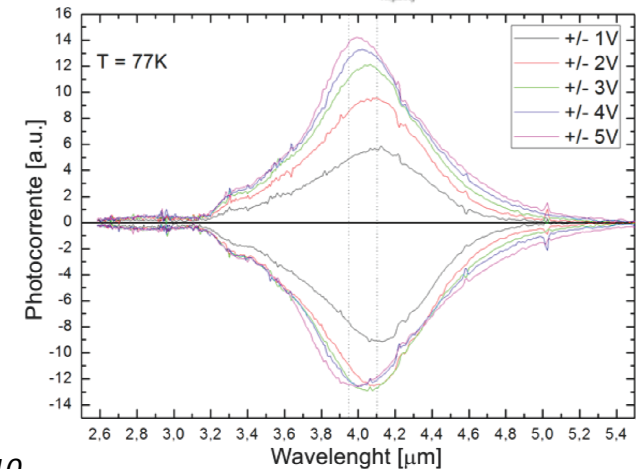
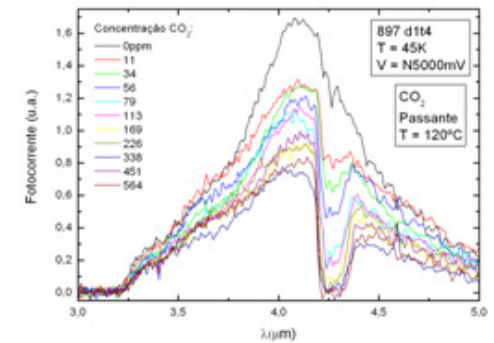
Equivalent to best values found in the literature

Figuroa et al, SBMicro 2013 accepted

Figuroa et al, BWSP 2013



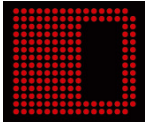
CO₂ sensing



Micha et al, ENMC 2010

Micha et al, BWSP 2011



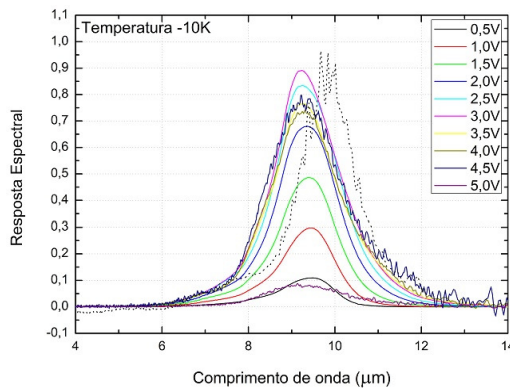


Mastering the working mechanisms and the technology of fabrication of mid-infrared semiconductor photodetectors

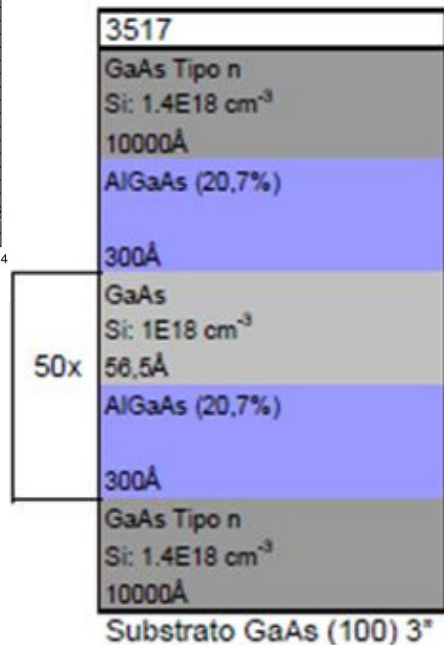
Production of different photodetectors

Quantum well infrared photodetectors - QWIPs

GaAs/AlGaAs QWIPs

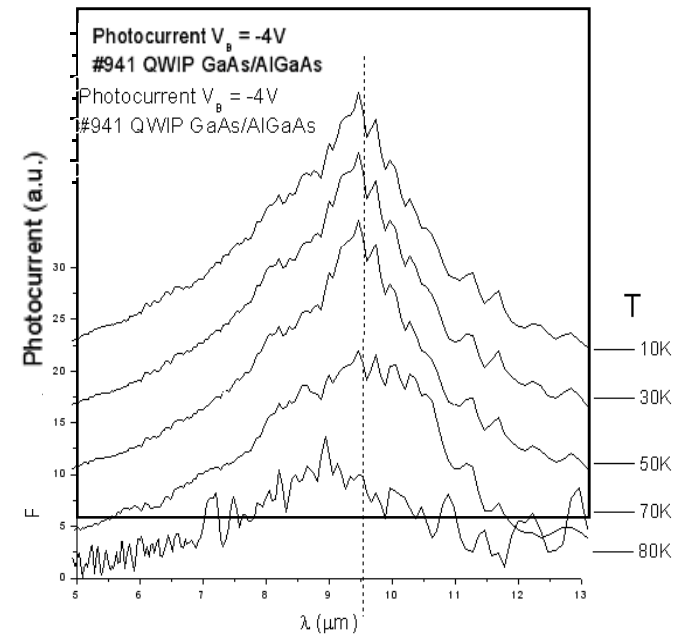


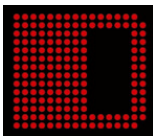
NO_x and methane sensing



Fernandes et al, ICSNN 2012

Free space communication or 300 K imaging



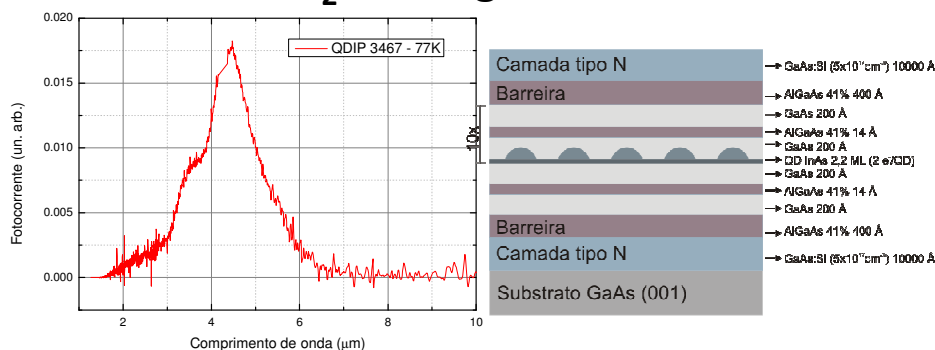


Mastering the working mechanisms and the technology of fabrication of mid-infrared semiconductor photodetectors

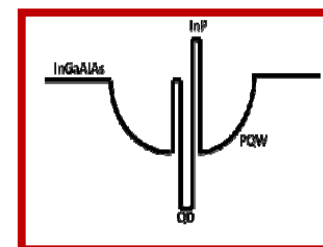
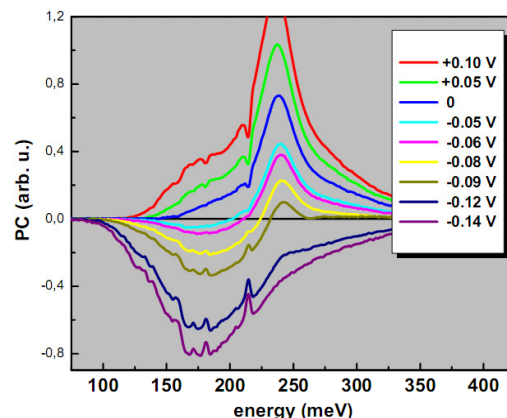
Quantum dot infrared photodetectors

Maia et al, ICSNN 2012,
Maia et al, J. Appl. Phys. to be published

CO₂ sensing

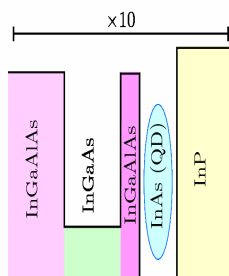
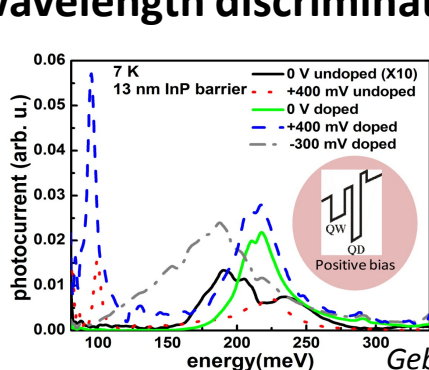


Two color detector



Penello et al BWSP. 2009

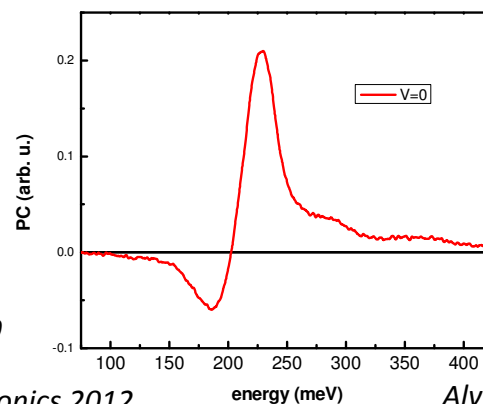
Record value of FWHM for fine wavelength discrimination



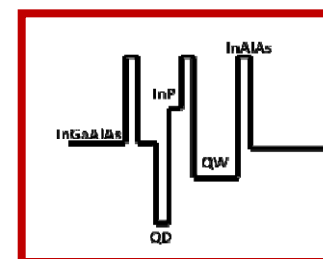
Gebhard et al J Modern Physics 2009

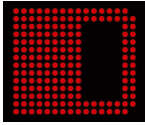
Gebhard et al LEOS 2009

Alvarenga et al IEEE Quantum Electronics 2012



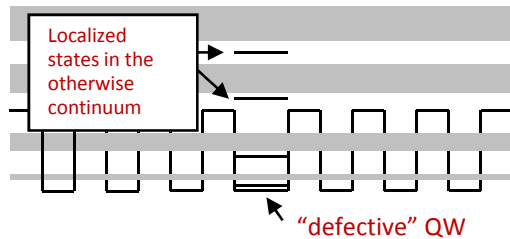
Alvarenga et al J. Appl. Phys. 2013





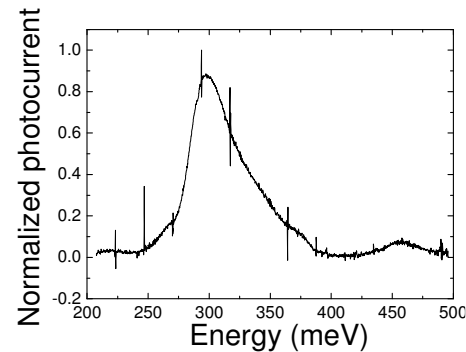
Mastering the working mechanisms and the technology of fabrication of mid-infrared semiconductor photodetectors

QWIPs based on superlattices



InP / InGaAs / InAlAs heterostructure

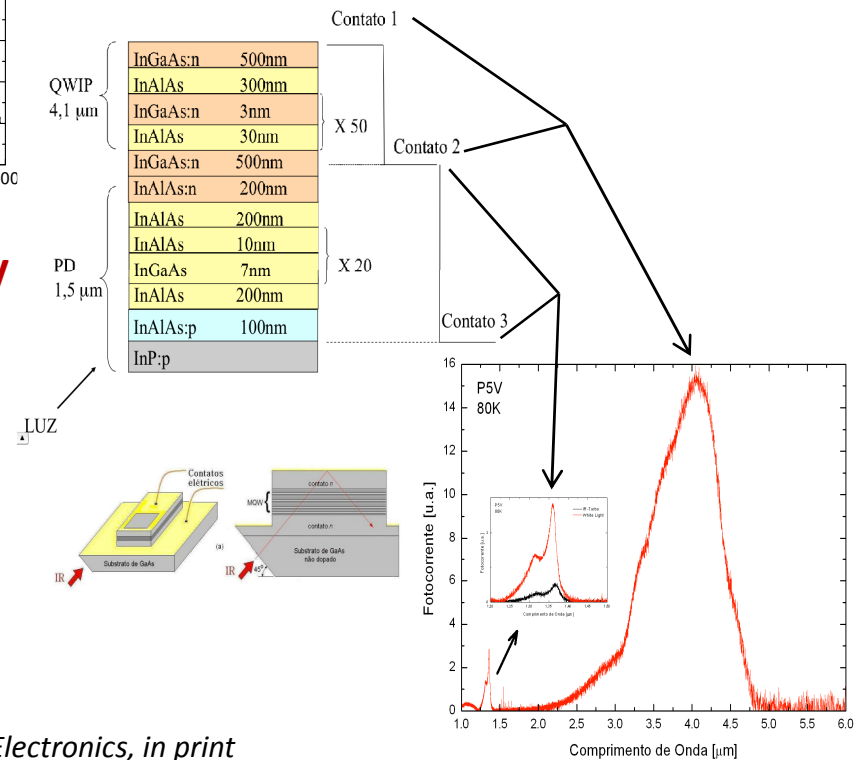
- Increase transition energy
- High selectivity
- Easy carrier extraction
- Tunability not limited by bandoffset
- Low thermal excitation



- **FWHM = 48 meV**
- **$\Delta\lambda/\lambda = 15\%$**

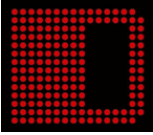
Penello et al IEEE Quantum Electronics, in print

Two coupled devices for two colors detection



Kawabata et al, Workshop IRT, 2010





Mastering the working mechanisms and the technology of fabrication of mid-infrared semiconductor photodetectors

Novel structures

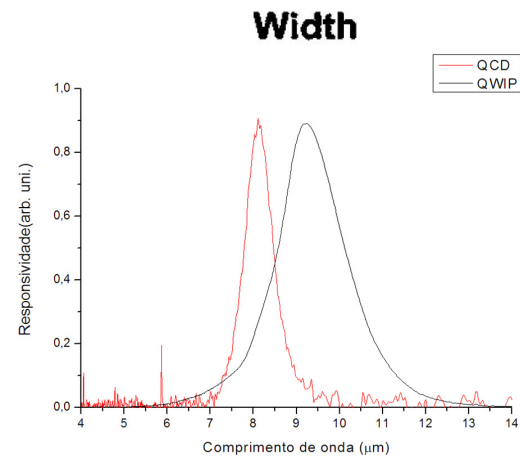
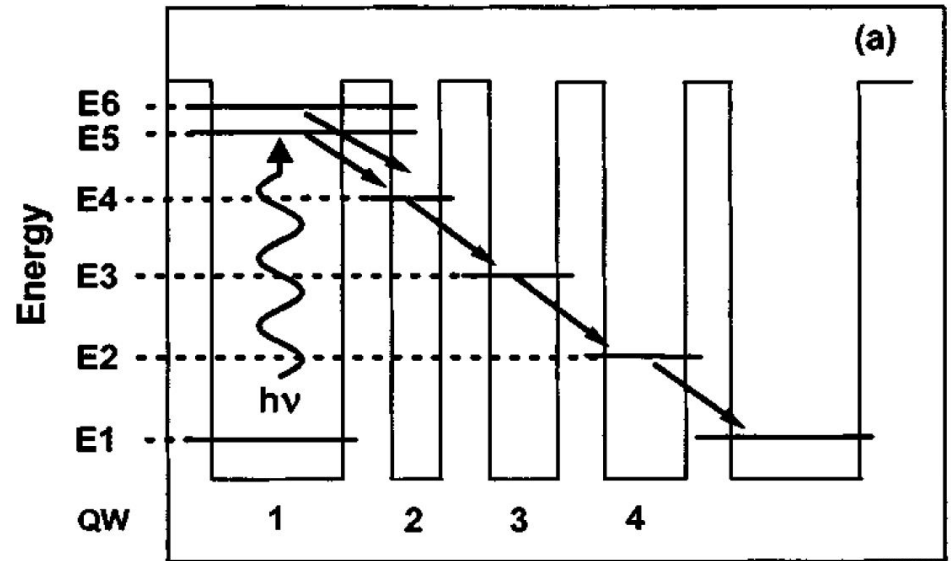
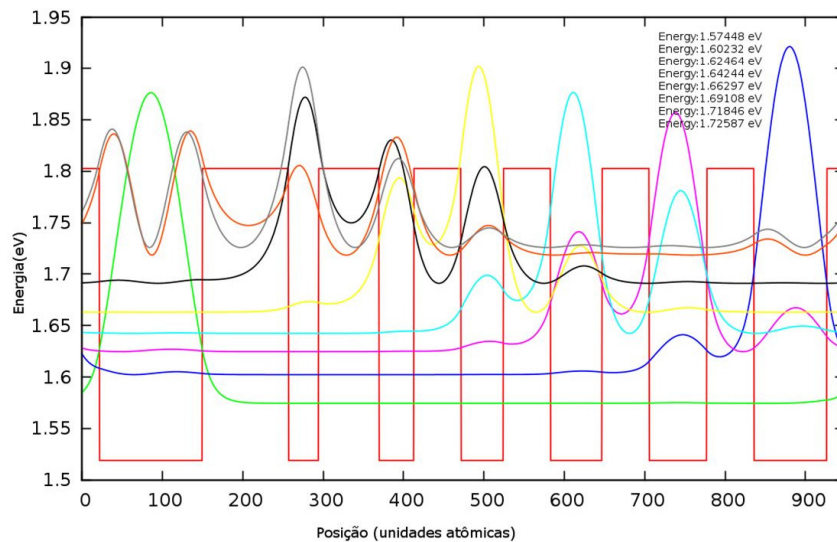
Quantum cascade IR detectors (QCD)

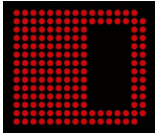
Advantages:

No bias

Extremely low dark current

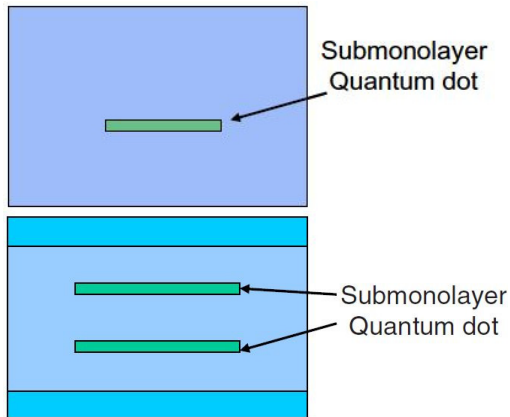
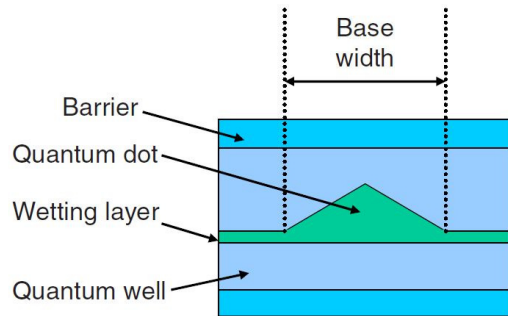
Higher temperature operation



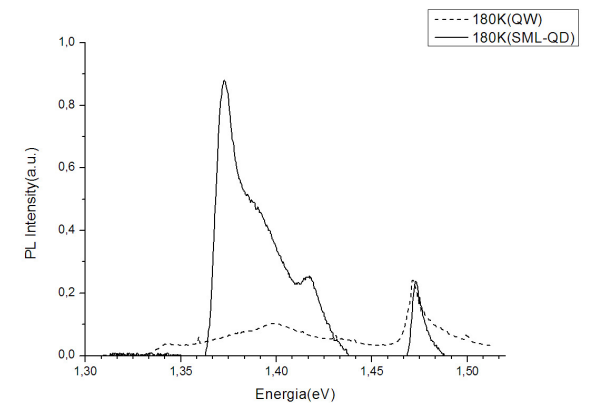
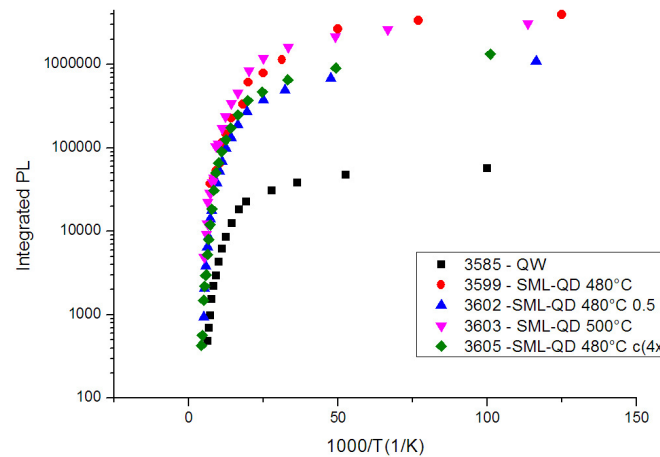
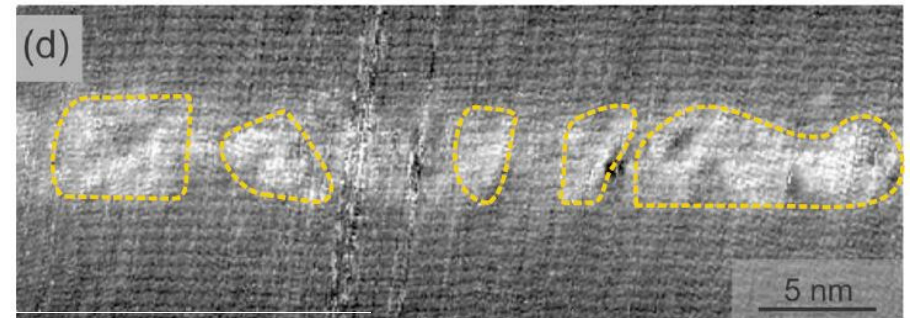


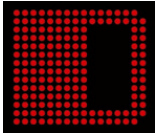
Mastering the working mechanisms and the technology of fabrication of mid-infrared semiconductor photodetectors

Sub-monolayer quantum dots and QDIPs



Control of dot size
Lateral confinement should improve
the performance of QDIPs

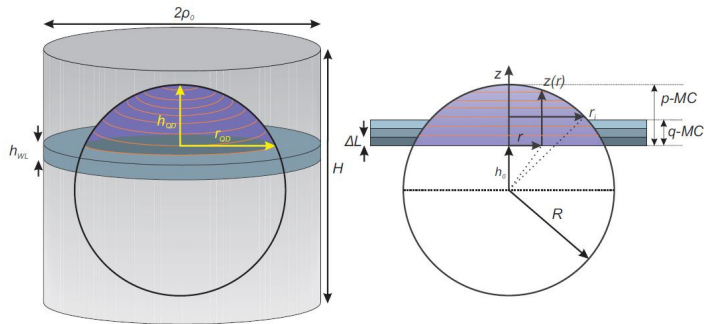




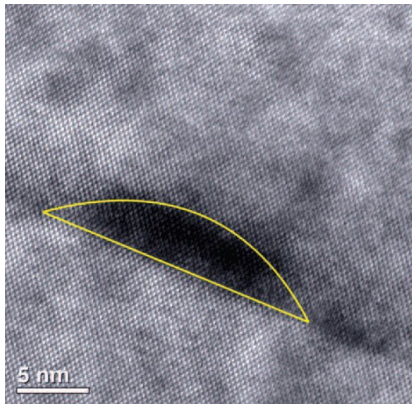
Understanding of the physical mechanisms involved in current generation and collection

Modelling/Simulation

In segregation



Change in energy levels

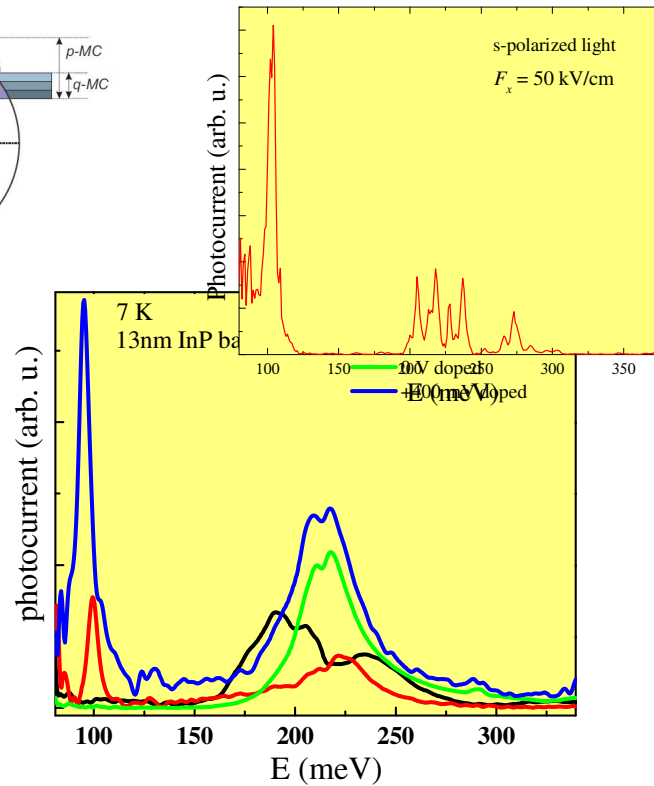


Maia et al, J. of Phys. D 2012

Schwan wt al, Appl. Phys. Lett. 2011

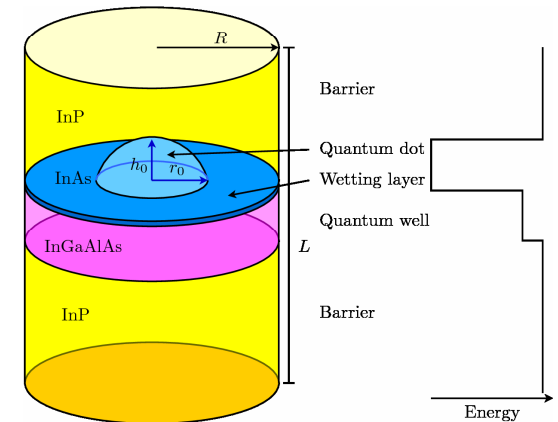
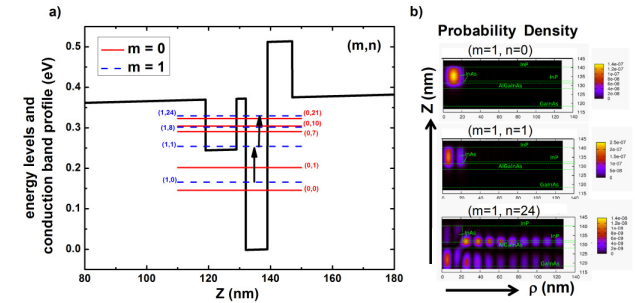
Martini et al, J. Vac. Sci. and Technol. 2010

Split-operator Multi photon process



Degani et al, J. Appl. Phys. 2011

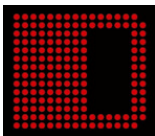
3D effective mass calculations



Auger scattering

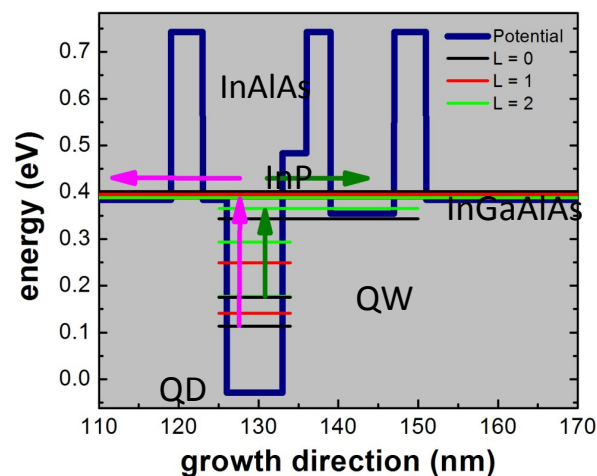
Gebhard et al, J. Appl. Phys. 2011



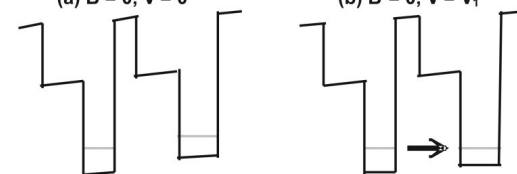
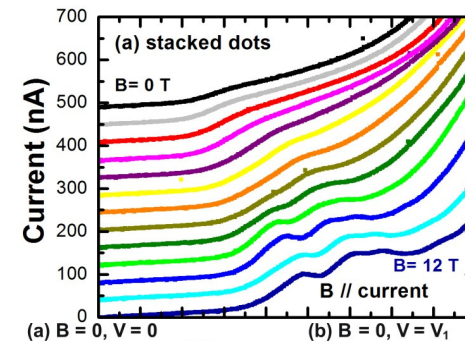
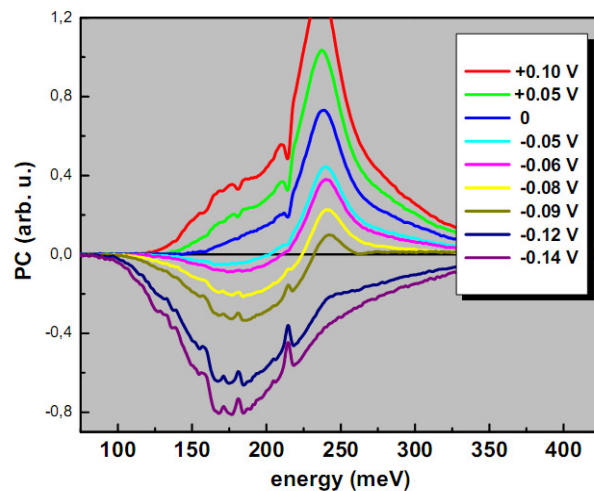
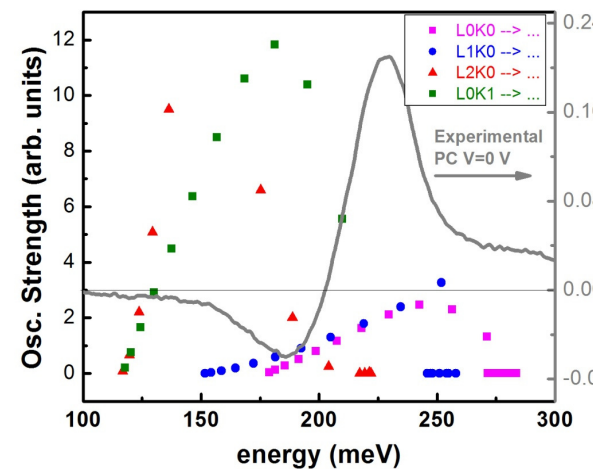
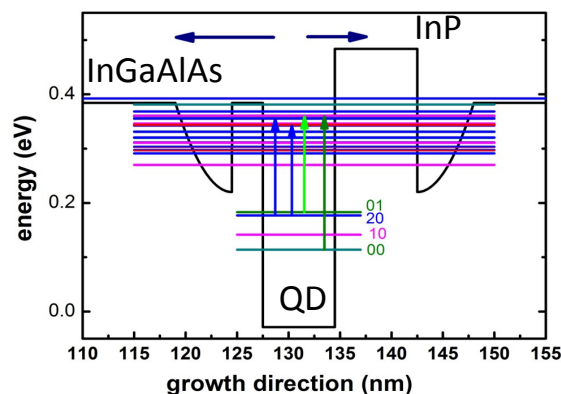


Understanding of the physical mechanisms involved in current generation and collection

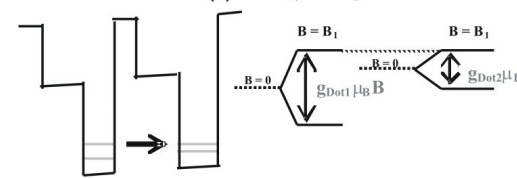
InGaAlAs/InAlAs/InAs/InP/InGaAs



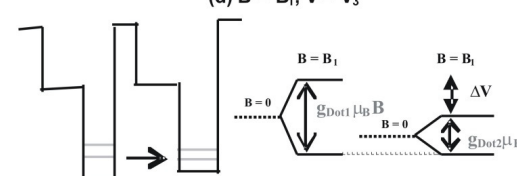
InGaAlAs/InAs/InP/InGaAs



(c) $B = B_1, V = V_2$



(d) $B = B_1, V = V_3$

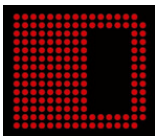


Tunneling between zero dimensional states with spin filtering

Silva et al, J. Appl. Phys. 2011

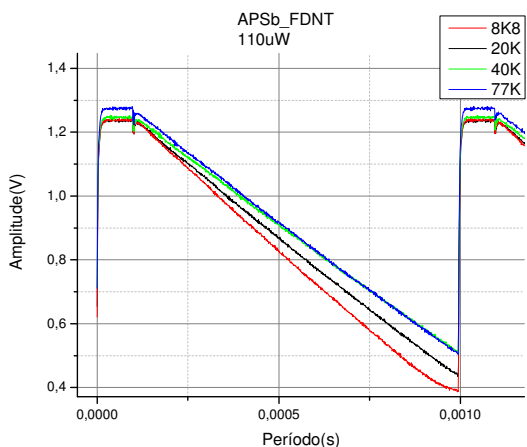
Alvarenga et al, J. Appl. Phys. 2013



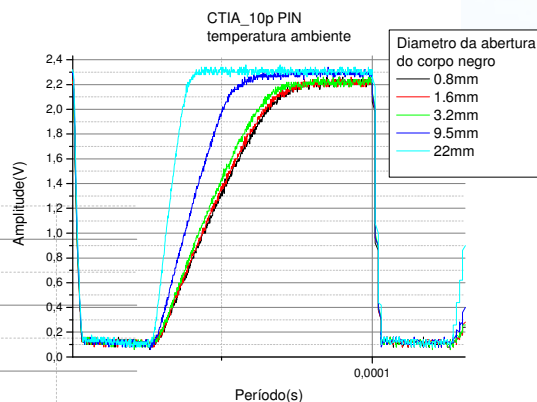
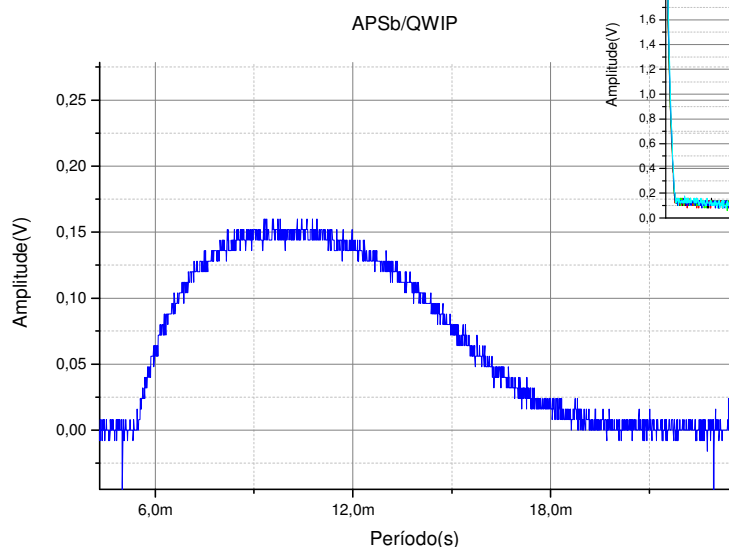
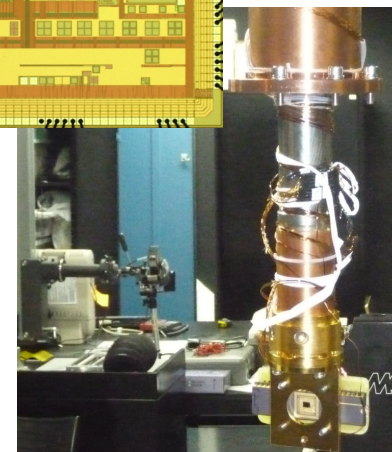
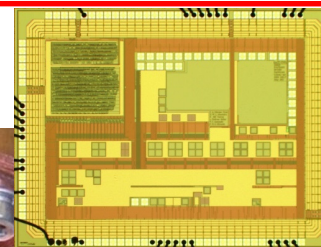
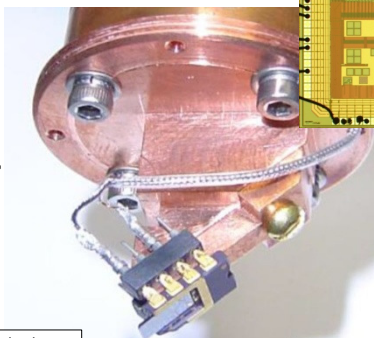


Development of the required circuitry for the read-outs of the photodetectors

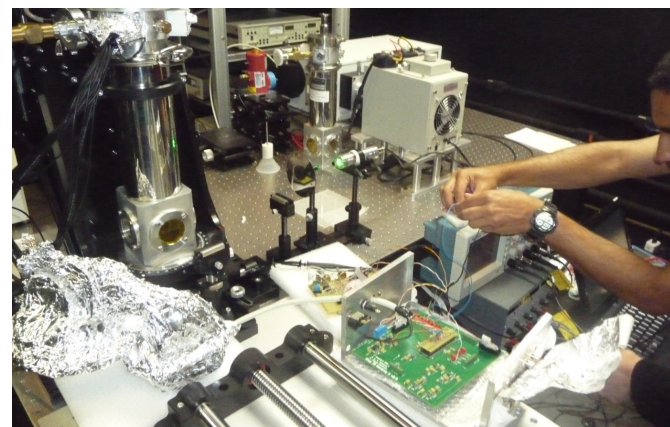
ROIC para detectores no infravermelho



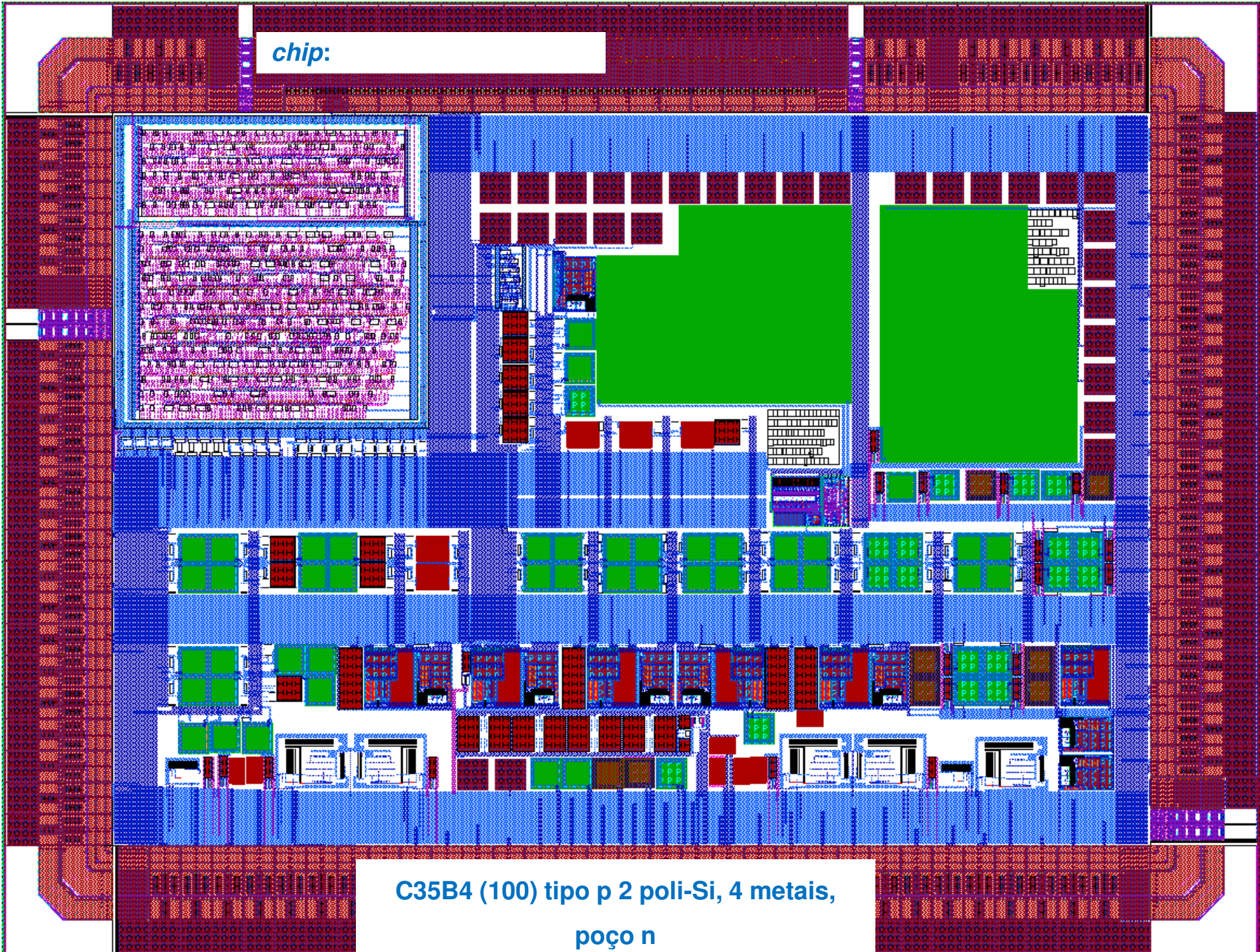
- First ROIC designed in Brazil and working at 300 K and even at low temperatures for hybridization with QWIPs and QDIPs



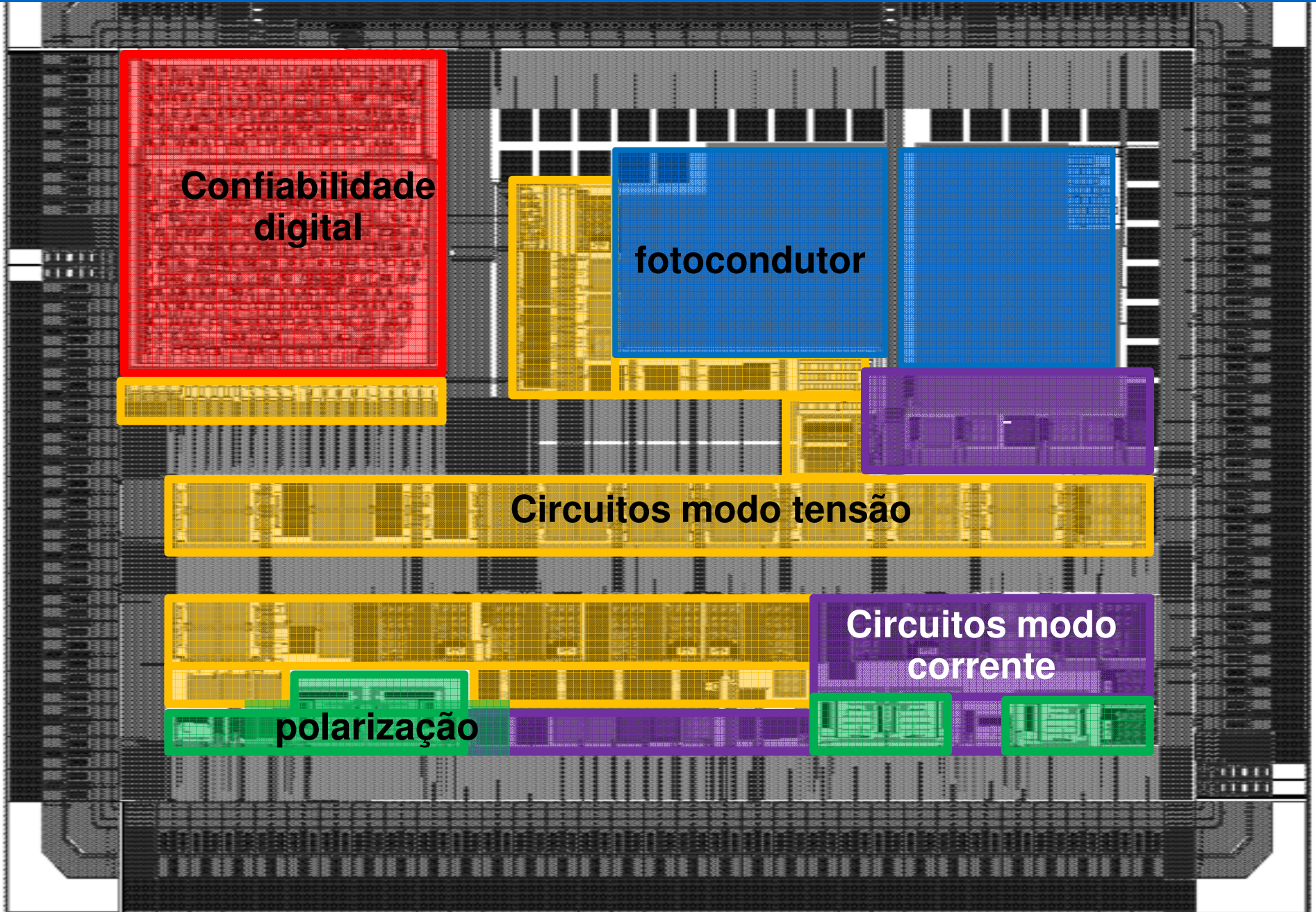
- The ROIC coupled to a QWIP and a QCD without optical modulation

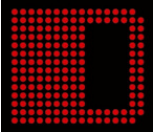


chip:

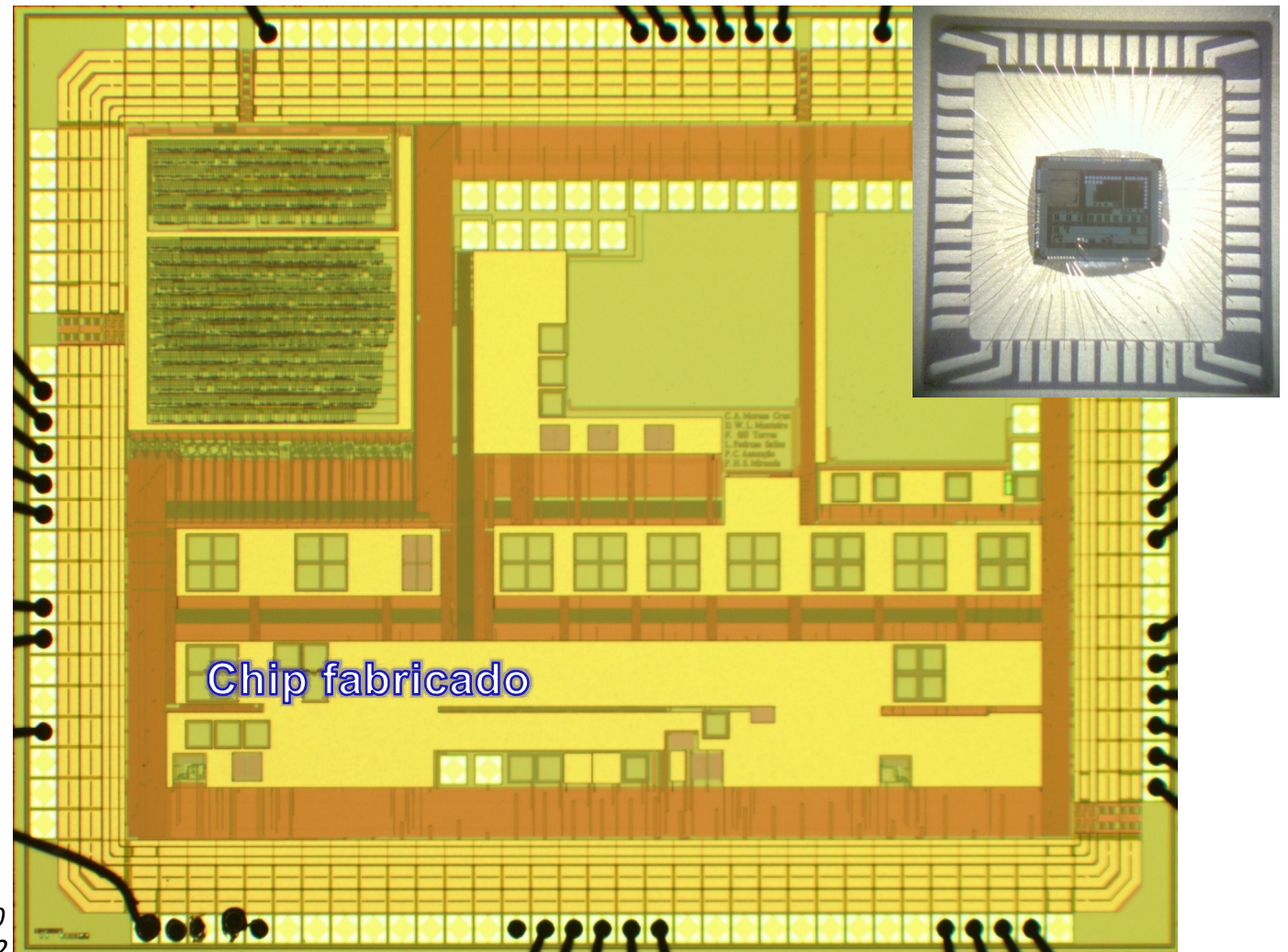


C35B4 (100) tipo p 2 poli-Si, 4 metais,
poço n

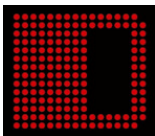




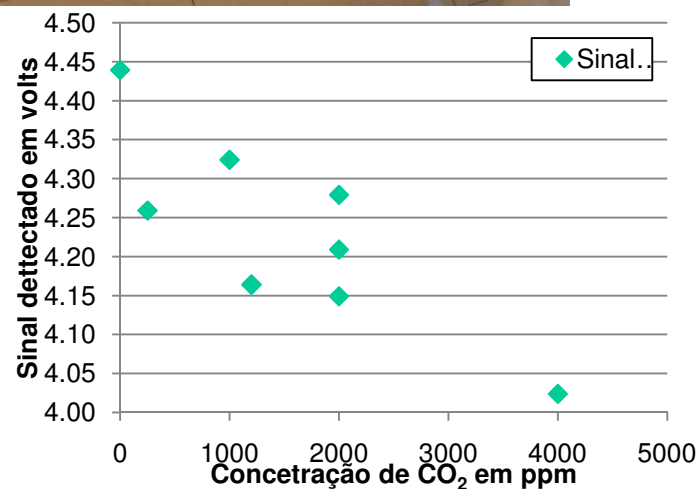
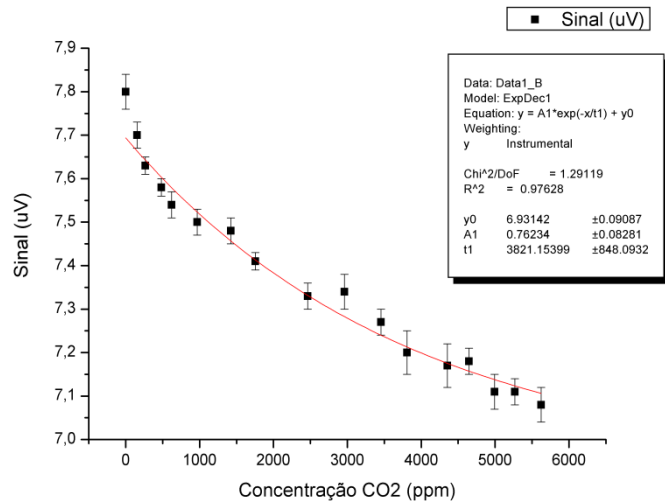
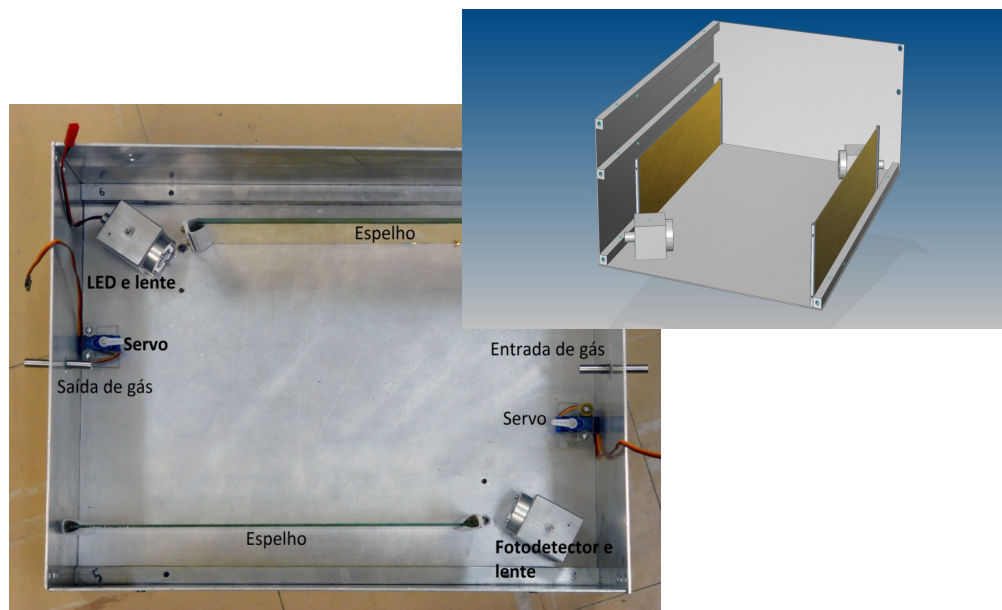
Development of the required circuitry for the read-outs of the photodetectors

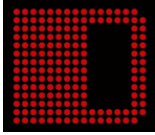


Salles et al, IEEE Sensors Journal 2009
Retes et al, Microelectron. Journal 2010
Coura et al, Sensors and Actuators 2012

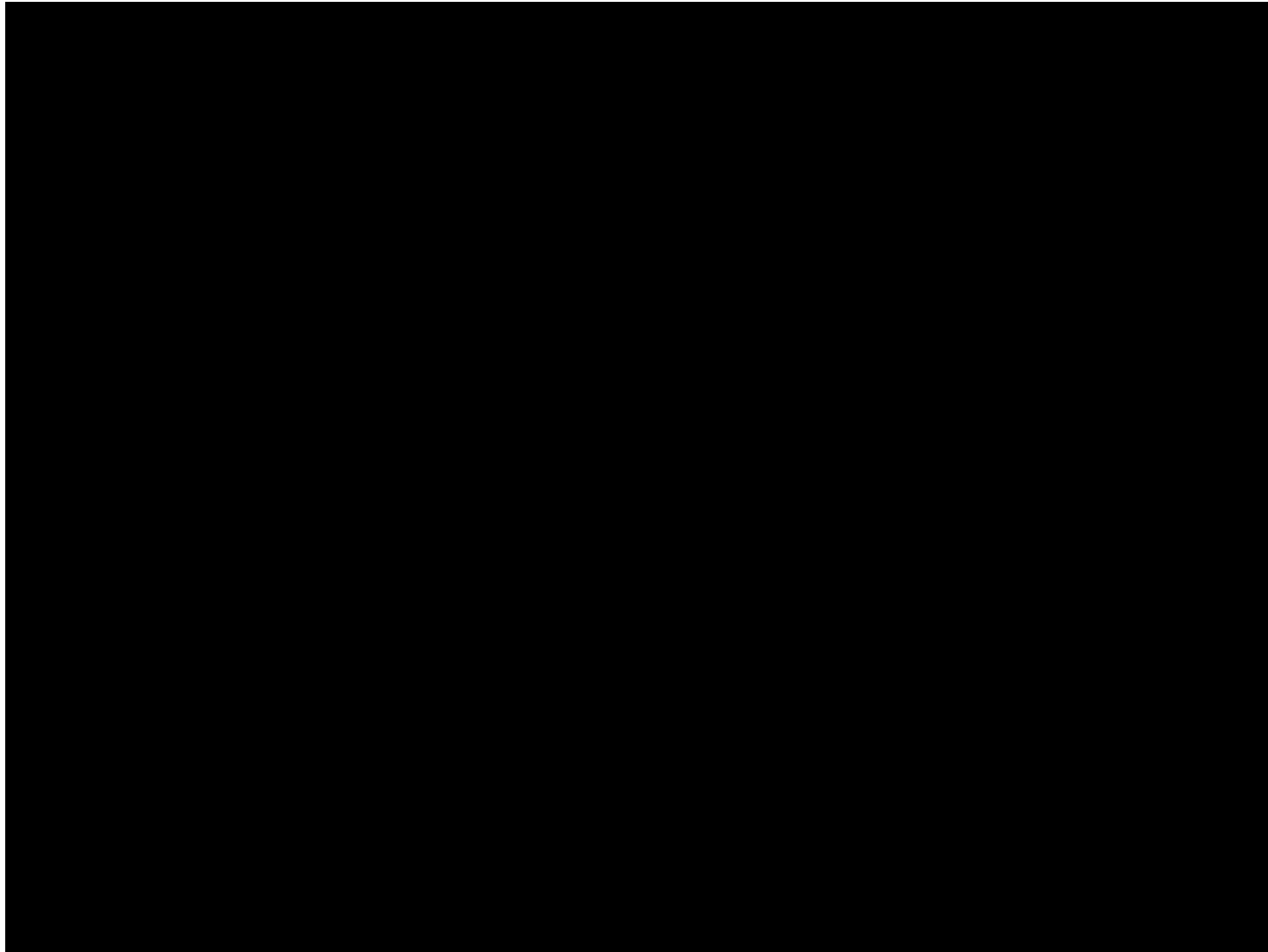


Design and fabrication of equipment which uses photodetection for relevant applications



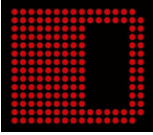


Design and fabrication of equipment which uses photodetection for relevant applications



INSTITUTO NACIONAL DE CIÊNCIA E TECNOLOGIA
NANODISPOSITIVOS SEMICONDUTORES

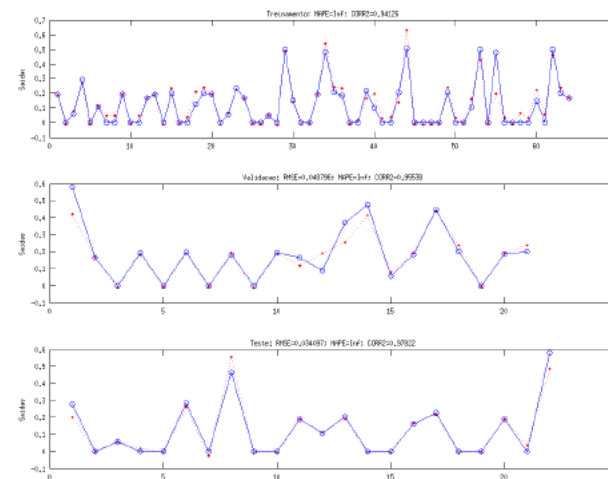
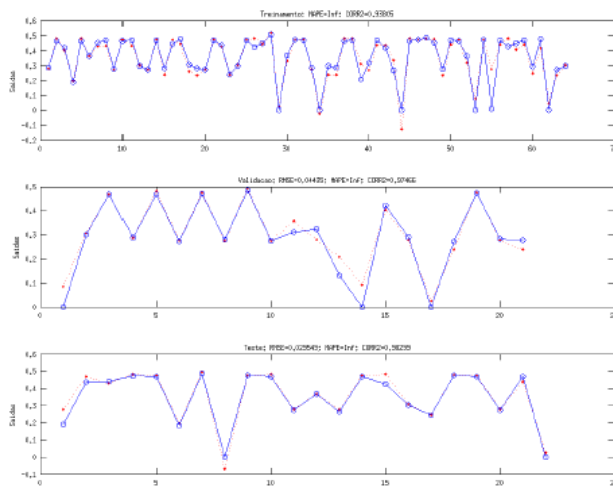




Inverse design

What are the synthesis parameters to achieve a sample with specific characteristics?

- 1) Get a pool of information from **previous experiments** in NanoTrack
- 2) Apply a computer system in order to learn from **previous data**
- 3) Optimize synthesis parameters in order to **find the desired structure**



Singulani, et al, ICAM 2009

Dias et al, IEEE C. Evol. Computing 2011

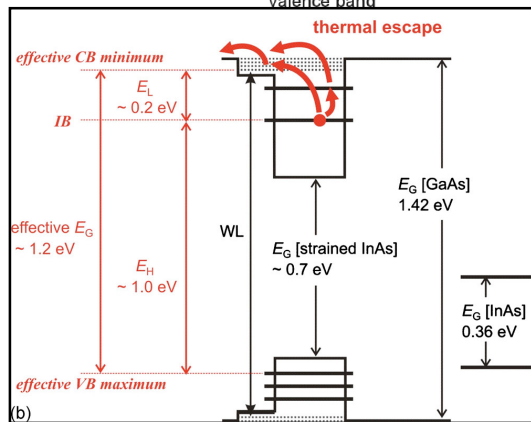
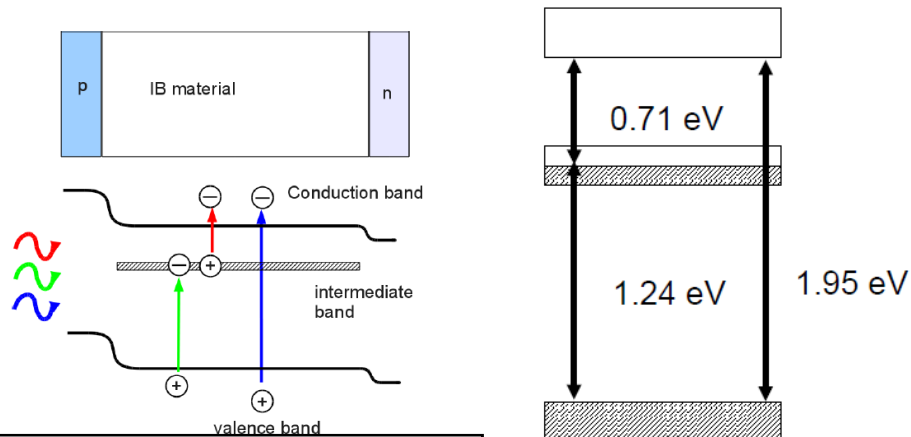
- Blue line: real values
- Red line: predicted values.





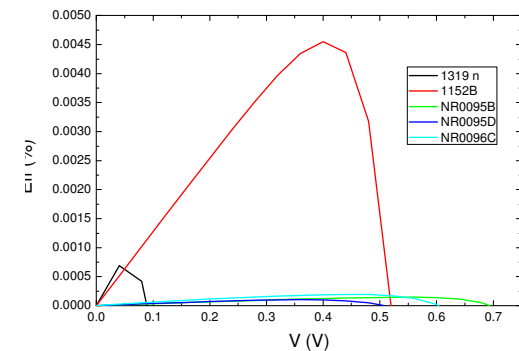
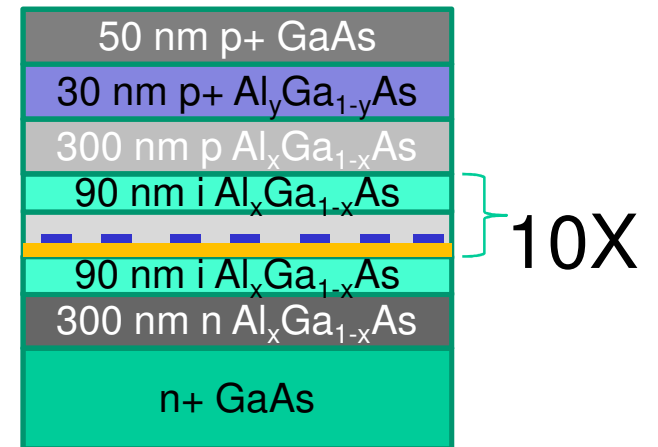
Development of solar cells based on nanostructures

Intermediate band solar cells



InAs/GaAs
Mostly investigated

InAs/AlGaAs
Our proposal for
1.95, 1.24 and 0.71 eV



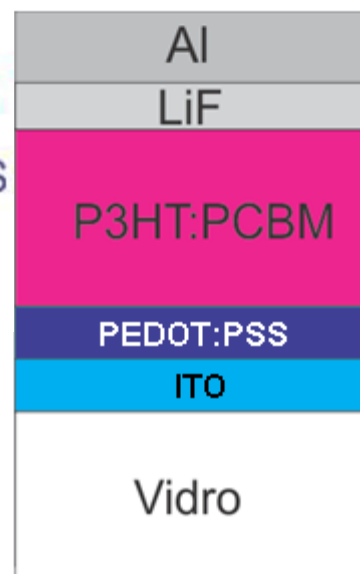
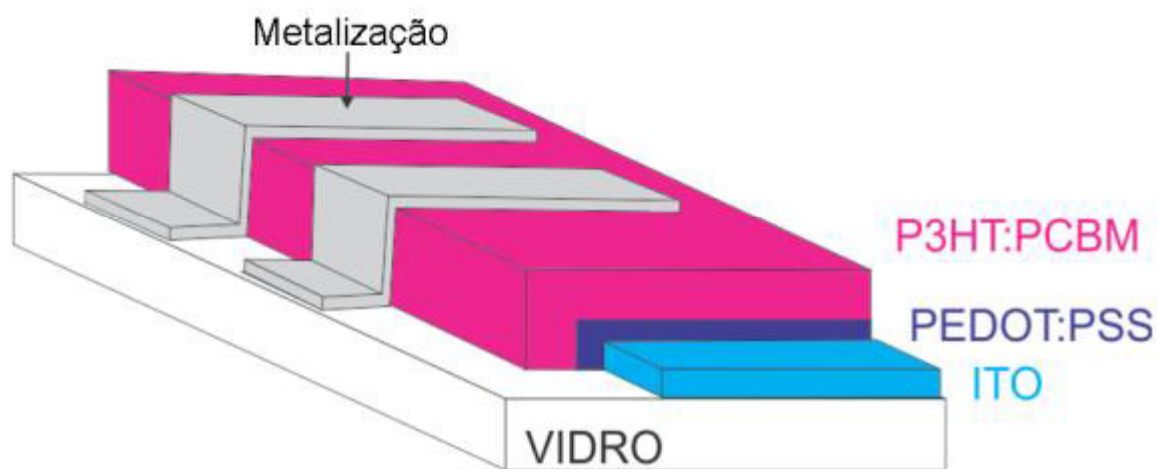
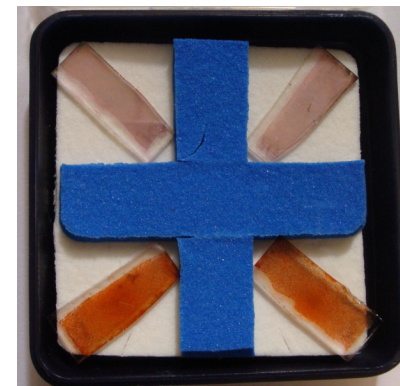
Micha et al, SBMicro 2013 accepted



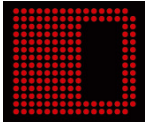


Development of solar cells based on thin films

Titanium oxide thin film to improve the efficiency of polymer solar cells

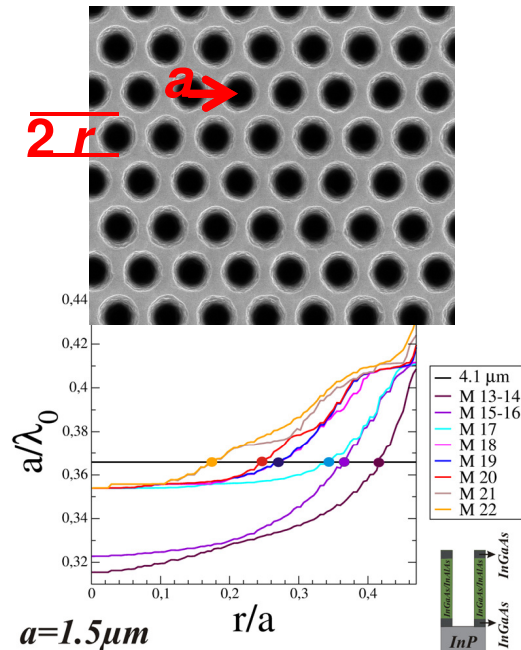


Araujo et al, *Organic Electronics*, 2012
Silva et al, *Polymer Physics*, 2010
Valadares et al, *Sensors and systems*, 2009

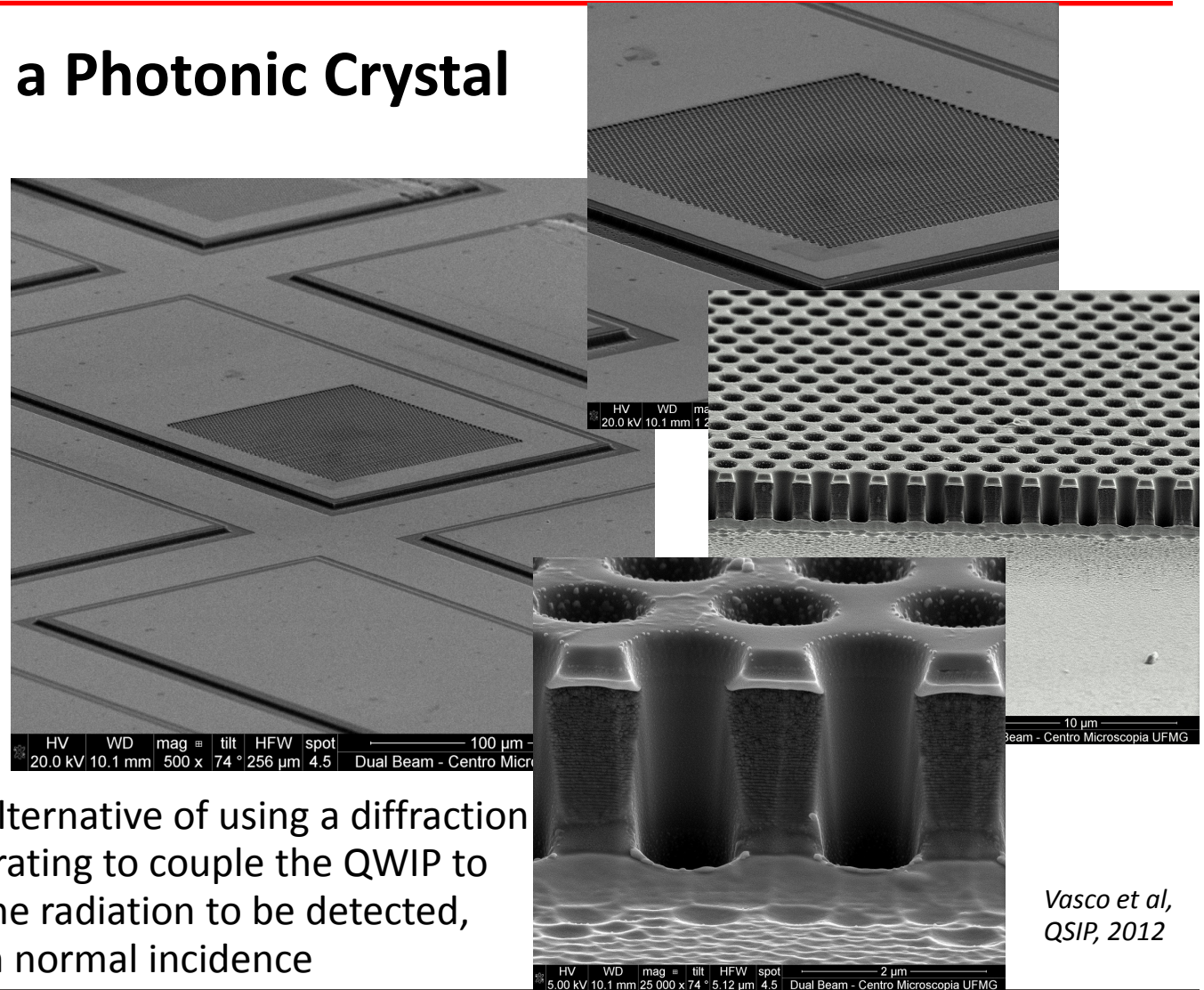


Group insertion in the international scenario with the development of novel semiconductor nanodevices

QWIPs coupled to a Photonic Crystal



$r=0.175a$	$r=0.245a$	$r=0.269a$	$r=0.344a$	$r=0.365a$	$r=0.415a$
21 22	20	18 19	17	15 16	13 14
$E_z = 0.036$ $E_z = 0.041$	$E_z = 0.003$	$E_z = 0.220$ $E_z = 0.211$	$E_z = 0.2$	$E_z = 0.038$ $E_z = 0.037$	$E_z = 0.030$ $E_z = 0.029$





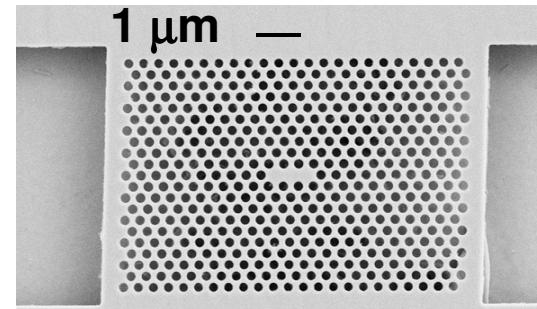
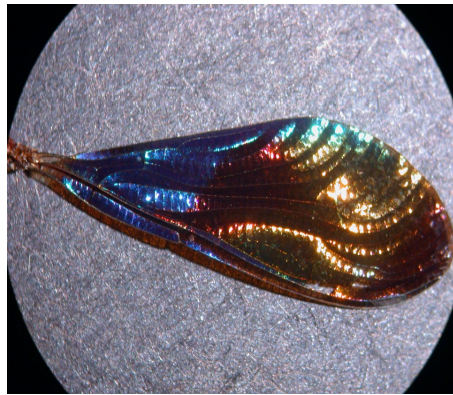
Group insertion in the international scenario with the development of novel semiconductor nanodevices

Fano resonances in photonic crystals

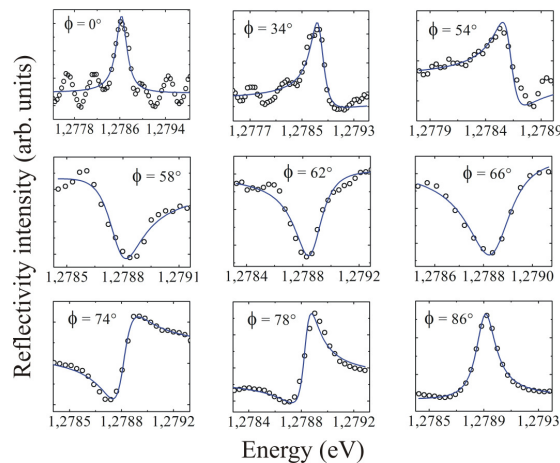
L3 photonic crystal cavities

Nature's photonic crystal

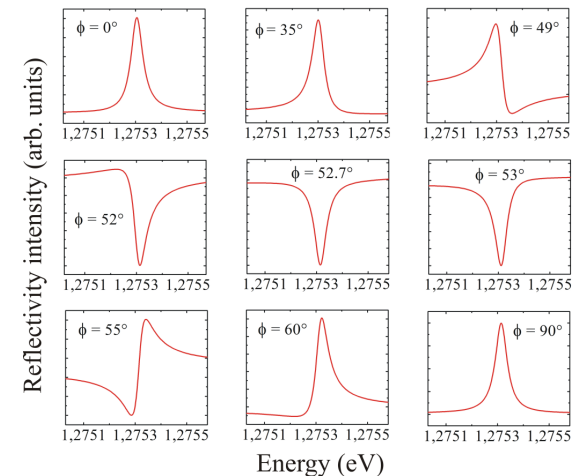
Wing of *Chautopteryx*



Experiment

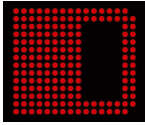


Theory



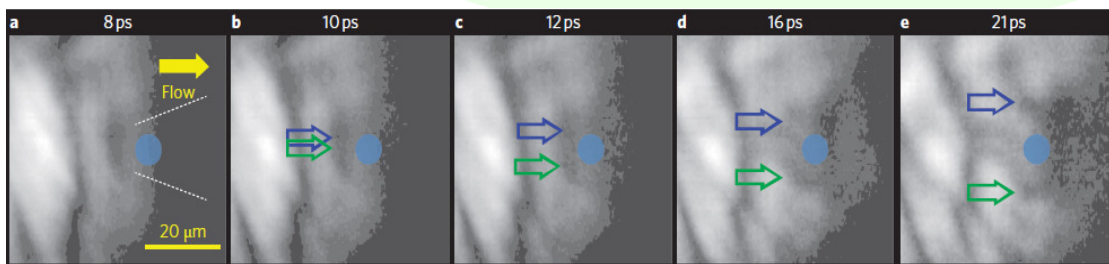
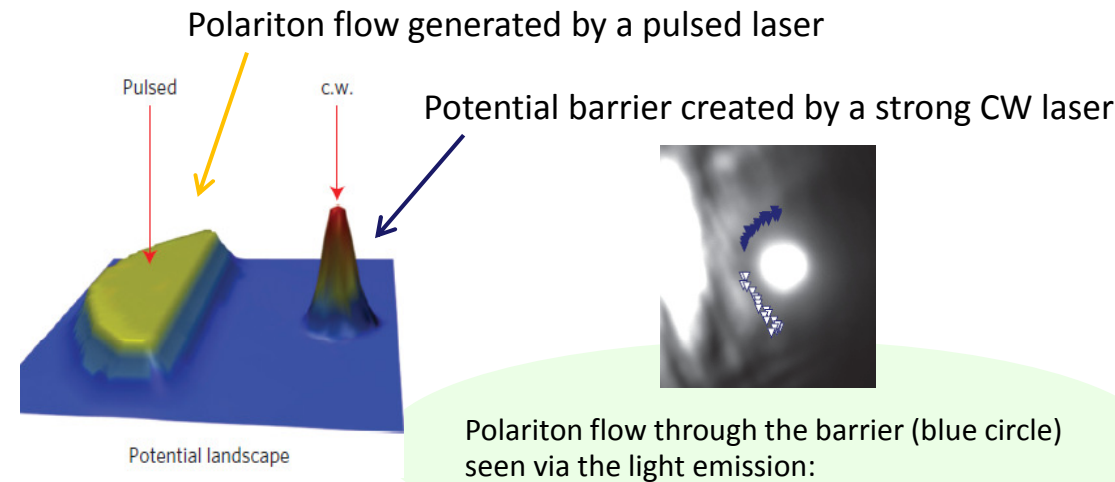
Valentim et al., *Applied Physics Letters* **102**, 111112 (2013)





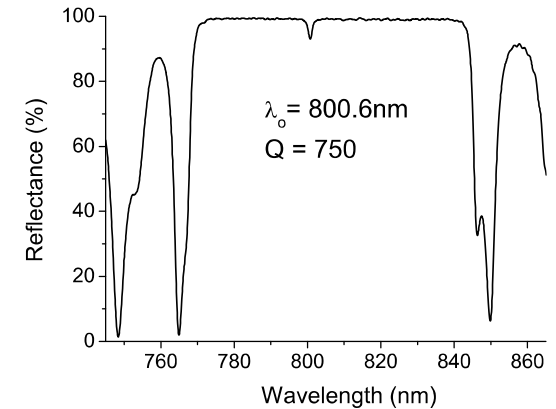
Group insertion in the international scenario with the development of novel semiconductor nanodevices

Flow of polaritons through an optically created potential barrier

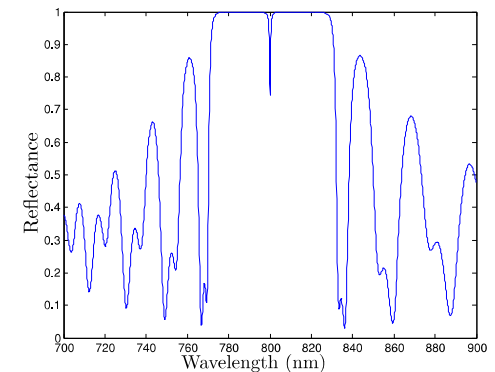


Sanvitto et al., *Nature Photonics* **5** 610 (2011)

Determining the optimized architecture of microcavities for best device performance using GA

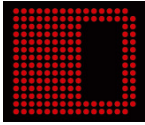


Mirrors of $\text{Al}_{0.2}\text{Ga}_{0.8}\text{As}/\text{AlAs}$



Mirrors of $\text{Al}_{0.17}\text{Ga}_{0.83}\text{As}/\text{Al}_{0.88}\text{Ga}_{0.12}\text{As}$

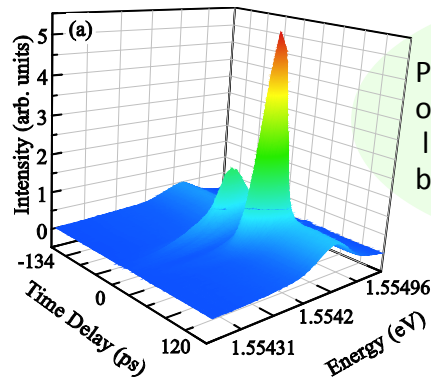




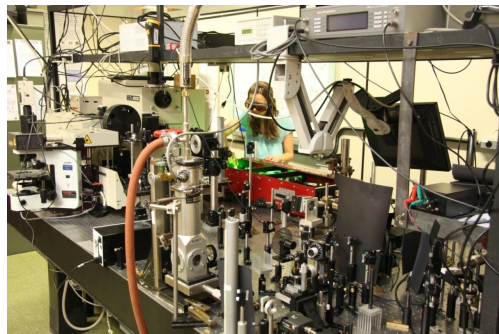
Group insertion in the international scenario with the development of novel semiconductor nanodevices

Polaritons in microcavities

- Pseudo spin dynamics of exciton-polaritons in semiconductor microcavities
- Longitudinal-transversal polariton splitting in semiconductor microcavities
- Parametric oscillation: polaritons population dynamics in a semiconductor microcavity

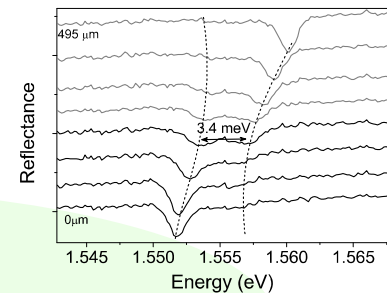
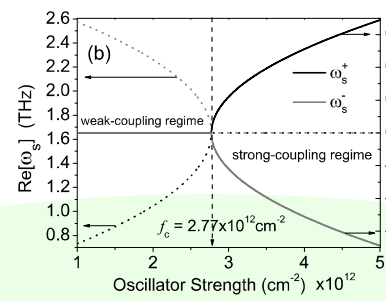
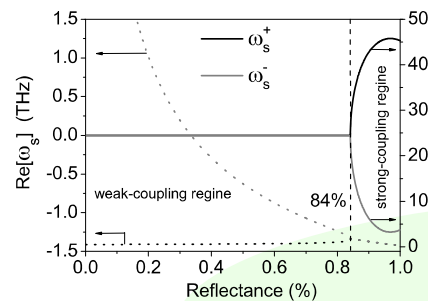


Polariton parametric oscillation observed in the lower branch luminescence excited resonantly by 100 femtosecond pulse laser.



Polaritons laser

- Development of an optical transistor using semiconductor microcavities



Conditions for strong coupling regime

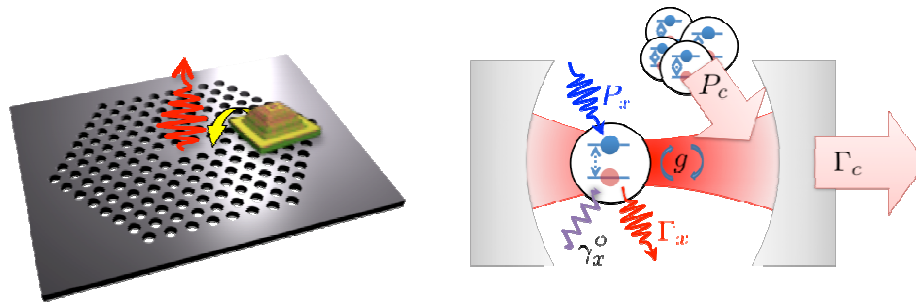
Matinaga et al, OECS 2009
Matinaga et al, ICPS 2010





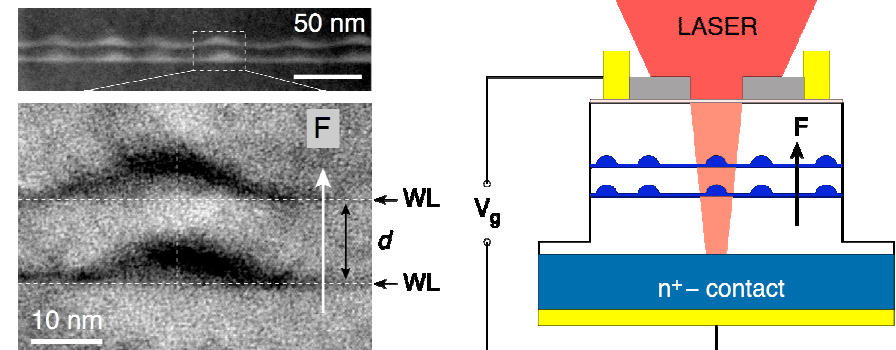
Group insertion in the international scenario with the development of novel semiconductor nanodevices

Theory of quantum dots in microcavities



1. A. Laucht et al. *Phys. Rev. Lett.* **103**, 087405 (2009)
2. A. Laucht et al. *Phys. Rev. B* **82**, 075305 (2010)
3. F. P. Laussy et al. *Phys. Rev. B* **84**, 195313 (2011)
4. F. O. Prado et al. *Phys. Rev. A* **84**, 053839 (2011)
5. W. J. Lima and J. M. Villas-Bôas, to be published.
6. A. Freitas and J. M. Villas-Bôas, to be published.

Molecules of quantum dots



- Transparency electromagnetically induced
- Coherent control
- Quantum computing
- Energy transparency
- Spin manipulation

1. H. S. Borges et al. *Phys. Rev. B* **81**, 075322 (2010)
2. M. M. Santos et al. *Phys. Rev. A* **85**, 032323 (2012)
3. H. S. Borges et al. *Phys. Rev. B* **85**, 115425 (2012)
4. K. Müller et al. *Phys. Rev. Lett.* **108**, 197402 (2012)
5. J. M. Villas-Bôas, to be published.
6. G. Azevedo and J. M. Villas-Bôas, to be published



International insertion

Collaborations and exchanges

- TU-Wien strong collaboration with the groups of Profs Karl Unterrainer and Gottfried Strasser
- **University of Sheffield with the group of Prof. Skolnick**
- Universidade de Antióquia, with the group of Prof. Boris Anghelo Rodriguez Rey
- **Princeton University/MIRTHE with the group of Professor Claire Gmachl**
- Laboratoire de photonique et nanostructures with the group of Dr. Jean Dagobert
- **Middle East Technical University with the group of Prof. Cengiz Besikci**
- Univesité du Languedoc Montpellier with Professor Francis Guastavino
- **Univesidade Nacional da Colômbia, Bogotá with Prof. Herbert Vinck Posada**
- Universidade Católica de Louvain (Belgica) with Benoit Hackens
- **NN Lecce-CNR, Itália collaboration with Daniel Sanvitto**
- Université Claude Bernard Lyon 1, with Prof. Dr. Guo-Neng Lu e Prof. Dr. Patrick Pittet
- **Université Joseph Fourier – Grenoble, Prof.Dr. Gilles Sicard and Prof.Dr. Skandar Basrour**
- Tohoku University – Sendai , Prof. Dr. Shuji Tanaka and Prof. Dr. Tomohiro Ishikawa
- **Delft University of Technology – Delft , Prof.Dr. Patrick J. French and Prof.Dr. Albert Theuwissen**
- Technische Universität Kaiserslautern – Kaiserslautern with Prof. Dr. Norbert Wehn





Human Resources/Education

I. International exchange

- Germano Penello, Ph.D. student at Princeton University and now going for a post-doc
- Déborah R. Alvarenga, Ph. D. student at TU-Wien
- Daniel Micha going for sandwich in Freiburg, Germany
- Thiago Moura, Ph. D. student at Tohoku University - Tanaka Lab - Sendai/Japan
- Carlos Augusto Cruz, Ph. D. student at Université Joseph Fourier, Grenoble, France
- Patrick dos Santos, , Ph.D. student at Université Claude Bernard Lyon 1 - INL – Lyon, France
- Three participations at ESONN (European School of Nanosciences and Nanotechnologies)
- Six French undergraduate students in Brazil
- Students to and from Colômbia
- Luciana Dornellas, at Alcatel France for a post-doc
- Dr. Roberto Jakomin from Italy-France post-doc
- Dr. Loïk Gence from Belgium as a post-doc
- Prof. Mauricio Pires spent a sabbatical leave at Alcatel, France
- Prof. Patrícia L Souza spent a sabbatical leave at TU-Wien

II. Science without Borders

5 undergraduate students

4 graduate students

III. Fellowships in Brazil from INCT Capes and CNPq

- *4 PDJ*
- *4 Post-doc*
- *1 Post-doc abroad*
- *2 Sandwich abroad*
- *19 DTI*
- *3 Masters*
- *4 Doctor degrees*
- *30 IC*
- *8 AT*



Human Resources/Education

IV. Industry/ Training

- Students working on topics which are strategically relevant
- Close interaction with industry
- Favorable conditions for the creation of *spin-offs*
- Training of microscopists
- Students in contact with the industries and government offices with which we collaborate
- One Ph.D. working in a company in the field

V. New placements

- 20 Master students continued to a Ph. D. in the field within the INCT-DISSE
- 2 Master students working in labs of interest in the field
- 5 Ph. Ds. working as post-doc in the field within the INCT-DISSE
- 4 Ph. Ds. are professors now, three within the field within the INCT-DISSE
- 3 Ph. Ds. working at companies
- Omar Villela Neto now professor at UFMG
- Luciana Pedrosa Salles now professor at UFMG
- Pablo Valentim now professor at UNII - BH
- José Maria Villas Boas now professor at UFU
- Marcelo Maialle and Marcos Degani now professors at Unicamp, Limeira



Human Resources/Education

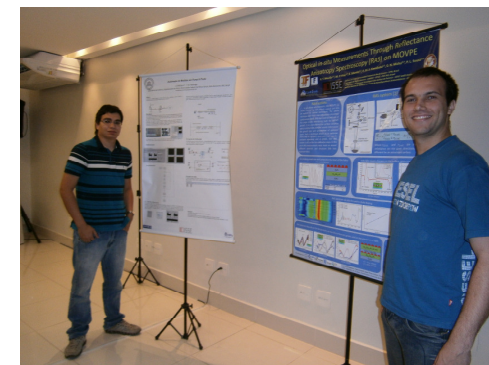
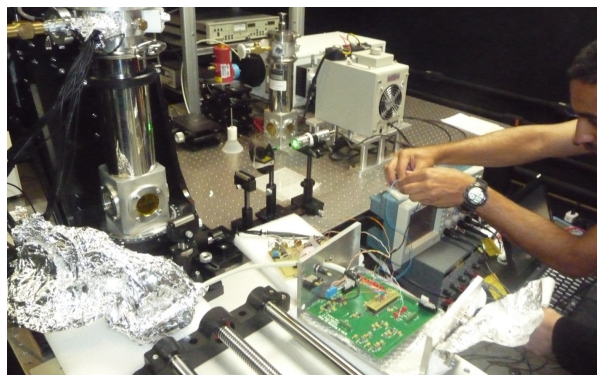
VI. Numbers

Underway

- 7 post-docs
- 4 DTI
- 22 PhDs
- 8 Masters
- 40 IC
- 3 AT

Finished

- 7 post-docs
- 15 DTI
- 12 PhDs
- 35 Masters
- 48 IC
- 5 AT

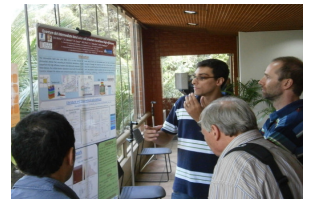




Human Resources/Education

VII. Promotion of workshops and schools

1. Summer School on Fundamentals and Materials for Novel Sensors, 2009, International
2. IEEE/CASS Workshop on Image Sensors, 2009 Regional
3. II Workshop on Effects of Ionizing Radiation in Electronic and Photonic Devices for Space Applications, 2009, International
4. EULASUR Workshop From Materials to Products, 2011, International
5. BRASSON – Escola Brasileira em Nanotecnologia e Nanociência, 2011
6. Workshop on Infrared Technology, 2011, National
7. I Escola de Verão em Computação do PPGCC/DCC/UFMG, 2012, National
8. Semana Nacional de Ciência e Tecnologia, Portas abertas do IF, 2012, Regional
9. PUC+Energia 2012, National
10. Workshop in Solar Cells, 2012, National





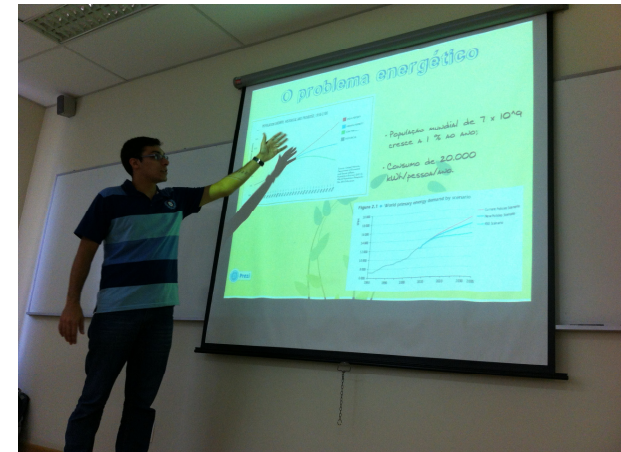
Human Resources/Education

VIII. Graduate and undergraduate programs

1. Sensors and attenuators at ITA with the participation of our members from IEAv
2. Engineering of Nanotechnology at PUC-Rio to start in March 2011
with a weekly seminar since 2013 on Nanoscience and nanotechnology with top level invited speakers

VIII. New courses

1. Introdução a Nanotecnologia, PUC-Rio since 2009
2. Nanodispositivos, PUC-Rio since 2009
3. Nanocomputação, UFMG since 2011
4. Nanotecnologia computacional, UFMG since 2012
5. Nanotecnologia computacional, PUC-Rio since 2013
6. Detecção e análise de imagens, UFMG 2011
7. Física de Dispositivos Semicondutores, IEAv – ITA, 2012
8. Métodos Numéricos e Aplicações em Clusters- I, IEAv – ITA, 2012
9. Métodos Numéricos e Aplicações em Clusters- II, IEAv – ITA, 2012
10. Sensores II, IEAv – ITA, 2012
11. Óptica Moderna, UFAM since 2009
12. Heteroestruturas Semicondutoras, UFAM, 2010





Outreaching actions

Relation to society

Youtube
Facebook
Twitter
webpage



Science education

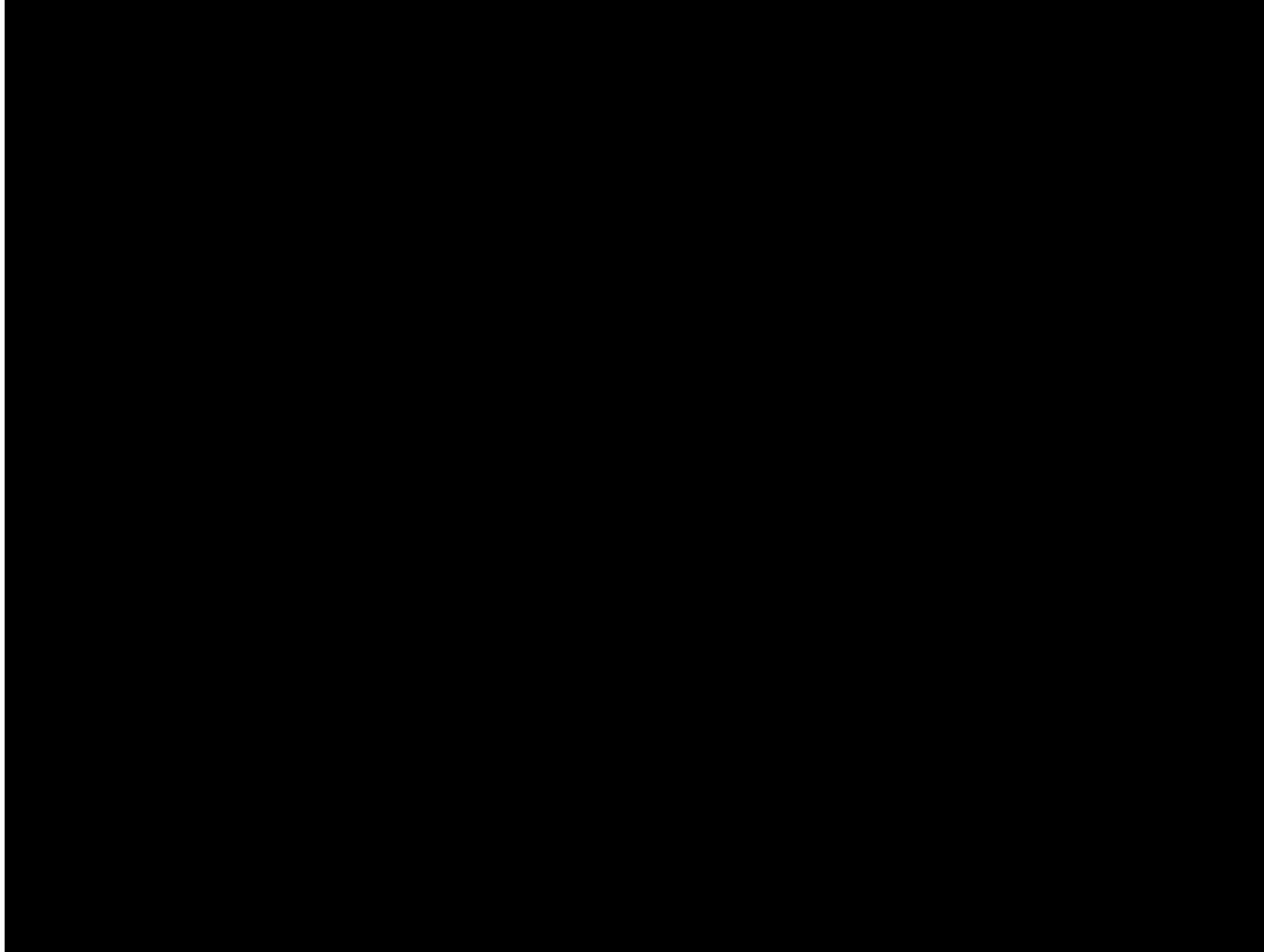
Video “Ver o Invisível”

- distributed in science museums, positive return
- available on the webpage and Youtube channel
- shown in many different events such as:
 - *PUC por um dia*
 - *Science Week*
 - *Knowledge Week UFMG*
 - *Science Circus*
 - *Innovation fair USP*
 - *Program ParFor/Novo Airão AM*
 - *Matogrossense school*





Outreaching actions



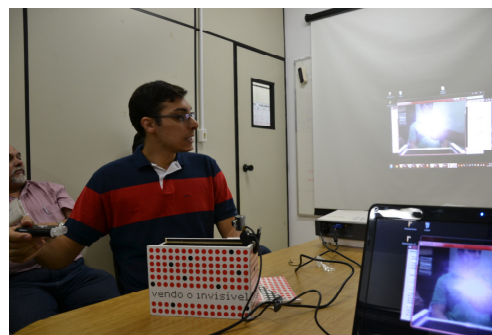
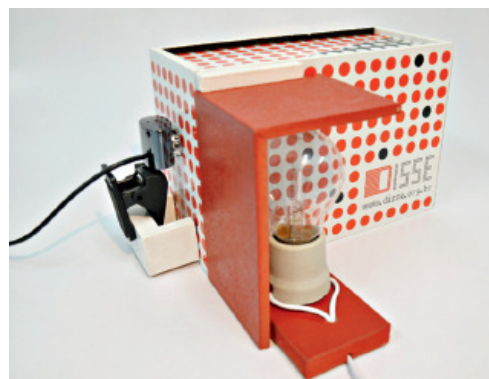
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Outreaching actions

Development and distribution of experimental kit on IR radiation: **VENDO O INVISÍVEL**



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Outreaching actions

Other activities

- Articles in journals such as Física na Escola and Revista Brasileira de Ensino
- Innumerous lab visits in most units for schools, graduate and undergraduate students
- Seminars to undergraduate students to attract them to the field
- Seminars in schools to raise the pupils' interest in science
- Participation in events such as Science and Literacy on Science Popularization

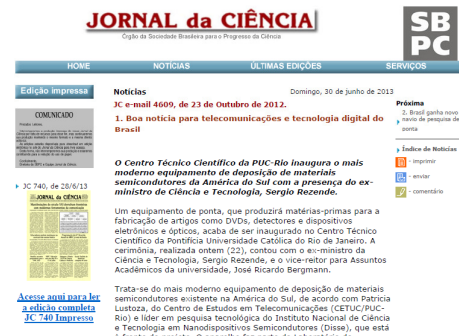


- Series of seminars on Nanotechnology for freshmen students
- Seminar on the present situation of science dissemination in Brazil during the XXVII Encontro de Físicos do Norte e Nordeste
- Nanokits for schools and undergraduate students
- EnTenda C&T



DISSE on the Media

- Two articles on the Faperj magazine in 2009
- **Do laboratório para o dia a dia** article at *Ciência Hoje* written by one of the members about the Nobel Prize winner last year
- **O admirável nanomundo**, article written by a member and published at *OGLOBO*
- Online interview with general public promoted by Fapesp
- **Nanotecnologia contribui para áreas como a medicina**, article at *Folha de São Paulo, Guia de Profissões* with contribution from members.
- **Pensando pequeno**, article on *.EDU* interview with a member.
- Interview for *Tribuna de Minas*
- Inauguration of new equipment for producing semiconductor material had more than 20 insertions in the media
- Article at *Gazeta do Amapá* about new lab equipment installed





DISSE on the Media

Development of chip for read-outs of photodetectors was on the news

28 mai 2013 | Pesquisadores do INCT-MN ganham destaque na revista Scientific Reports - Nature

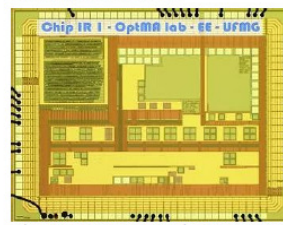
28 mai 2013 | **INCT-DISSE desenvolve chip de silício para leitura de fotodetectores**

27 mai 2013 | Lançadas novas chamadas do Ciência sem Fronteiras para graduação sandwich

- CNPq news
- Jornal da Ciência
- Inovação Tecnológica

Brasil desenvolve chip de silício para leitura de fotodetectores

Com informações do CNPq - 31/05/2013



Batizado de IR1, o chip foi fabricado com a tecnologia CMOS de 0,35 micrômetro. [Imagem: INCT-DISSE]

visão noturna -, e podem contribuir para o monitoramento agrícola e pecuário, entre outras aplicações.

Segundo o professor Davies William de Lima Monteiro, o chip está sendo testado para futura aplicação em sistemas para detecção de radiação infravermelha.

O pesquisador explica que a faixa do infravermelho, com comprimentos de onda entre 2 e 10 micrômetros, apresenta potencial para aplicações militares, o que dificulta a importação de qualquer tipo de dispositivo ou sistema desse tipo.

O chip foi concebido por pesquisadores da Universidade Federal de Minas Gerais (UFMG), membro do INCT.

Tecnologia CMOS

Batizado de IR1, o chip foi fabricado com a tecnologia CMOS de 0,35 micrômetro.

"CMOS é a tecnologia dominante para circuitos integrados no mundo. Hoje, os sinais dos detectores quânticos desenvolvidos no país são medidos por meio de equipamentos geralmente grandes e de alto custo," explicou ele.

A ideia é que o novo chip monitore o desempenho de diversas topologias de circuitos integrados digitais e analógicos para leitura de sinais provenientes de fotodetectores quânticos iluminados por luz infravermelha.

"Pretendemos criar um produto 100% nacional que seja mais acessível a esse mercado em expansão no país e que poderá ser compatibilizado com a tecnologia microeletrônica nacional. Hoje, a Ceteq S.A. é uma das empresas que trabalham para implantação dessa tecnologia," disse Davies.

Fonte: Site Inovação Tecnológica - www.inovacaotecnologica.com.br

URL: <http://www.inovacaotecnologica.com.br/noticias/noticia.php?artigo=brasil-desenvolve-chip-silicio-leitura-fotodetectores>

<http://www.jornaldaciencia.org.br/Detail.jsp?id=87323>
<http://www.inovacaotecnologica.com.br/noticias/noticia.php?artigo=brasil-desenvolve-chip-silicio-leitura-fotodetectores&id=010110130531>

JORNAL da CIÊNCIA

Órgão da Sociedade Brasileira para o Progresso da Ciência



Edição Impressa

Notícias

13. INCT-DISSE desenvolve chip de silício para leitura de fotodetectores

O produto está sendo testado para futura aplicação em sistemas para detecção de radiação infravermelha

O denominado Chip IR1 foi fabricado com a tecnologia CMOS 0,35 micrometres e concebido por seis projetistas ao longo de cinco meses. Estiveram envolvidos neste projeto professores, alunos de graduação e de pós-graduação dos departamentos de Engenharia Elétrica e Engenharia Eletrônica, além do Programa de Pós-Graduação em Engenharia Elétrica, todos da Universidade Federal de Minas Gerais (UFMG), localizada na cidade de Belo Horizonte (MG), parceiros no INCT.

ter, 28 mai 2013

16:20:00 -

INCT-DISSE desenvolve chip de silício para leitura de fotodetectores

O projeto de pesquisa do Instituto Nacional de Ciência e Tecnologia em Nanodispositivos Semicondutores (INCT-DISSE) que prevê o desenvolvimento de um chip de silício para a leitura de sinais de fotodetectores começa a dar resultados promissores. A ideia é que o novo produto consiga verificar o desempenho de diversas topologias de circuitos integrados digitais e analógicos para o condicionamento e leitura de sinais provenientes de fotodetectores quânticos iluminados por luz infravermelha.

O denominado Chip IR1 foi fabricado com a tecnologia CMOS 0,35 micrometres e concebido por seis projetistas ao longo de cinco meses. Estiveram envolvidos neste projeto professores, alunos de graduação e de pós-graduação dos departamentos de Engenharia Elétrica e Engenharia Eletrônica, além do Programa de Pós-Graduação em Engenharia Elétrica, todos da Universidade Federal de Minas Gerais (UFMG), localizada na cidade de Belo Horizonte (MG), parceiros no INCT.

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Knowledge transfer to industry and government offices

Partners:



Investing in our development of infrared photodetectors for infrared cameras operating in the SWIR with financial support.



Joint project on infrared imaging, detectors delivered

OPTOVAC

Joint project with scholarship

IGAL Lentes Project on electrochromatic films



MINISTÉRIO DA CIÊNCIA E TECNOLOGIA
INSTITUTO NACIONAL DE PESQUISAS ESPACIAIS

+



Cooperation on the evaluation of radiation hardness of semiconductor devices, in special, infrared sensors



Personnel for free space optical communication testing



Ministério da Defesa, Pró-defesa

Association with National Labs

- *LABDIS (SisNano)*
- *LANano (SisNano)*
- *Rede Brasileira de Pesquisa e Instrumentação em Nanoespectroscopia Óptica*

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Knowledge transfer to industry and government offices

Involvement with public policies

Actions undertaken to build an infrastructure in the country for the production of infrared photodetectors:

JOINT VENTURE BETWEEN GOVERNMENT AGENCIES AND COMPANIES INTERMEDIATED BY INCT-DISSE

1) Proposal of creation of an Innovation Institute in Defense together with SENAI

- *Area of sensors responsibility of INCT-DISSE*
- *Discussions with SENAI, Ministry of Defense and FIESP*
- *Companies that have participated in the discussions: Mectron, Opto Eletrônica, Equatorial Sistemas, Optsensys, Navcon, Orbital e Luxtec.*



2) Proposal of the installation of a pilot plant for the development of infrared photodetectors and solar cells at Parque Tecnológico, São José dos Campos

- *Operation feasibility*
- *Project elaboration*
- *INCT-DISSE, Parque Tecnológico São José dos Campos, AEB, MD, Orbital*



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Knowledge transfer to industry and government offices

Technological products/technology transfer

1) QWIPs developed for CTE_x and prototypes delivered

2) Equipment for gas detection

3) Software development:

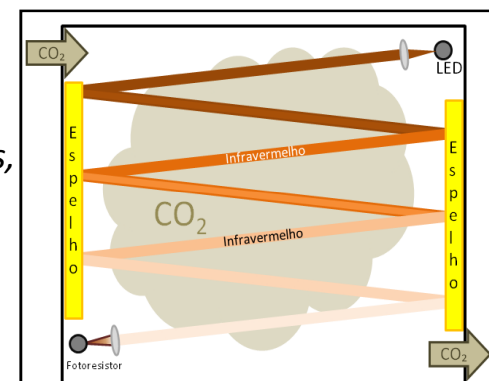
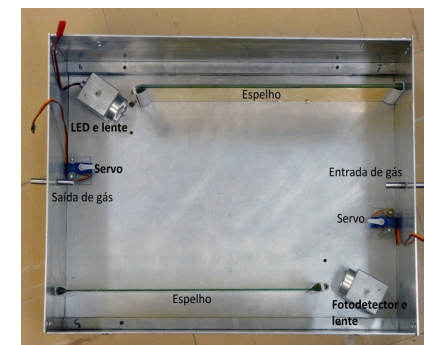
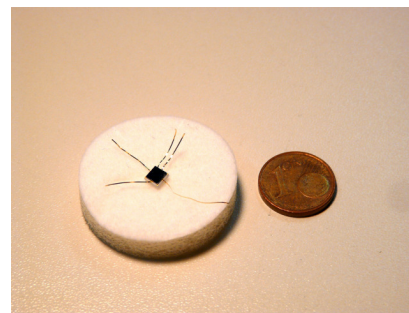
- Computational tool for designing lithographic masks for silicon convex microlenses, Davies William de Lima Monteiro, junho 2009.
- Quantum Well Software – version 4, Angelo Passaro, Wellington Palma Gonçalves, Roberto Yuji Tanaka, Nancy Mieko Abe, J. M. Villas-Boas, QWS v4, 2010.
- Integrated tool for optimization of circuit parameters of components of integrated circuits, Pablo Nunes Agra Belmonte, setembro 2012.
- μ CavitySim, Eduardo Adriano Cotta, Omar Paranaíba Vilela Neto, Fernando Carvalho Coelho e Eduardo Cesar Pimenta Ribeiro, 2013.

4) Granted patents:

- Método e aparato otimizador de eficiência de LEDs orgânicos.
- Método Otimizador de Desempenho de Células Solares e Aparato Otimizador de Desempenho.

5) Deposited patents:

- Dispositivo maciço encapsado com nanocone de carbono para microscopia e espectroscopia por varredura de sonda
- Dispositivo maciço com extremidade unidimensional para microscopia e espectroscopia por varredura de sonda





Cooperation with other INCTs

- INCT INEO of Organic Electronics
Conjugated polymers semiconductor devices (Luiz Alberto Cury)
and on Computational Intelligence (Marco Cremona)
- INCT of Quantum Information
Photodetectors for free space optical communication
(Jean Pierre von der Weid, Guilherme Temporão e
Guilherme Xavier)
- INCT FOTONICOM of Photonics for Optical Communication
Growth of semiconductor structures and use of processing facilities
(Newton Frateschi)
- INCT NAMITEC of Micro and Nanoelectronic Systems
Site-controlled nucleation of quantum dots of III-V semiconductors
(Rodrigo Prioli) and on CMOS chip 0.35 μm integrated circuit
(Petraglia and Gomes)
- INCT Carbon Nanomaterials
Carbon nanotubes for photosensitive devices (Marcos Pimenta)



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THANK YOU





Scientific and technological output

- Books 2
- Chapter of a book 1
- Scientific international journals 69
- Scientific national journals 3
- Presentations in international conferences 73
- Presentations in national conferences 63
- Softwares 4
- Patents 4



Main publications

- *Robust states in semiconductor quantum dot molecules*, H. S. Borges *et al*, Physical Review. B, **81**, 075322, (2010).
- *Self-Assembly Quantum Dots Growth Prediction by Quantum-Inspired Linear Genetic Programming*, Douglas Mota Dias *et al* "IEEE Congress on Evolutionary Computation" CEC2011, New Orleans, USA (2011).
- *Atomically resolved study of the morphological change of InAs/GaAs quantum dots layers by rapid thermal annealing*, J.G. Keizer *et al*, Applied Physics Letters **101**, 243113 (2012).
- *Exceptionally narrow band quantum dot infrared photodetector*, D. Alvarenga *et al*, IEEE Journal of Quantum Electronics, **48**, 1360-1366 (2012).
- *Asymmetry tuning of Fano resonances in GaAs photonic crystal cavities*, P. T. Valentim *et al*, Applied Physics Letters, **102**, 111112 (2013).

Main technological products:

- *Detectors QWIPs fornecidos ao Exército*, Rudy Kawabata *et al* (2012).
- *Chips para read-out de fotodetectores*, Davies William Lima Monteiro *et al* (2012).
- *Sistema de detecção de gases tóxicos*, Guilherme Torelly *et al* (2013).

